

Freescale Semiconductor, Inc.

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### **Kinetis KL25 Sub-Family**

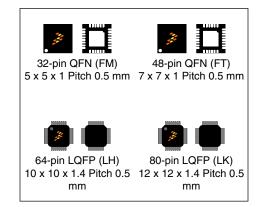
48 MHz Cortex-M0+ Based Microcontroller with USB

Designed with efficiency in mind. Compatible with all other Kinetis L families as well as Kinetis K2x family. General purpose MCU with USB 2.0, featuring market leading ultra low-power to provide developers an appropriate entry-level 32-bit solution.

#### This product offers:

- Run power consumption down to 47 μA/MHz in very low power run mode
- Static power consumption down to 2 μA with full state retention and 4 µs wakeup
- Ultra-efficient Cortex-M0+ processor running up to 48 MHz with industry leading throughput
- Memory option is up to 128 KB flash and 16 KB RAM
- Energy-saving architecture is optimized for low power with 90 nm TFS technology, clock and power gating techniques, and zero wait state flash memory controller

MKL25ZxxVFM4 MKL25ZxxVFT4 MKL25ZxxVLH4 MKL25ZxxVLK4



#### **Performance**

• 48 MHz ARM® Cortex®-M0+ core

#### Memories and memory interfaces

- Up to 128 KB program flash memory
- · Up to 16 KB SRAM

#### System peripherals

- Nine low-power modes to provide power optimization based on application requirements
- · COP Software watchdog
- · 4-channel DMA controller, supporting up to 63 request SOURCES
- Low-leakage wakeup unit
- SWD debug interface and Micro Trace Buffer
- · Bit Manipulation Engine

- 32 kHz to 40 kHz or 3 MHz to 32 MHz crystal oscillator
- Multi-purpose clock source
- 1 kHz LPO clock

#### **Operating Characteristics**

Voltage range: 1.71 to 3.6 V

#### **Human-machine interface**

- Low-power hardware touch sensor interface (TSI)
- Up to 66 general-purpose input/output (GPIO)

#### **Communication interfaces**

- USB full-/low-speed On-the-Go controller with onchip transceiver and 5 V to 3.3 V regulator
- Two 8-bit SPI modules
- One low power UART module
- · Two UART modules
- Two I2C module

#### **Analog Modules**

- 16-bit SAR ADC
- 12-bit DAC
- Analog comparator (CMP) containing a 6-bit DAC and programmable reference input

- Six channel Timer/PWM (TPM)
- Two 2-channel Timer/PWM modules
- · Periodic interrupt timers
- 16-bit low-power timer (LPTMR)
- · Real time clock





• Flash write voltage range: 1.71 to 3.6 V

• Temperature range (ambient): -40 to 105°C

#### Security and integrity modules

• 80-bit unique identification number per chip

#### Ordering Information <sup>1</sup>

| Part Number   | Me         | Memory    |    |
|---------------|------------|-----------|----|
|               | Flash (KB) | SRAM (KB) |    |
| MKL25Z32VFM4  | 32         | 4         | 23 |
| MKL25Z64VFM4  | 64         | 8         | 23 |
| MKL25Z128VFM4 | 128        | 16        | 23 |
| MKL25Z32VFT4  | 32         | 4         | 36 |
| MKL25Z64VFT4  | 64         | 8         | 36 |
| MKL25Z128VFT4 | 128        | 16        | 36 |
| MKL25Z32VLH4  | 32         | 4         | 50 |
| MKL25Z64VLH4  | 64         | 8         | 50 |
| MKL25Z128VLH4 | 128        | 16        | 50 |
| MKL25Z32VLK4  | 32         | 4         | 66 |
| MKL25Z64VLK4  | 64         | 8         | 66 |
| MKL25Z128VLK4 | 128        | 16        | 66 |

<sup>1.</sup> To confirm current availability of ordererable part numbers, go to <a href="http://www.freescale.com">http://www.freescale.com</a> and perform a part number search.

#### **Related Resources**

| Туре                | Description  | Resource                              |
|---------------------|--|---------------------------------------|
| Selector Guide      | The Freescale Solution Advisor is a web-based tool that features interactive application wizards and a dynamic product selector. | Solution Advisor                      |
| Product Brief       | The Product Brief contains concise overview/summary information to enable quick evaluation of a device for design suitability.   | KL2 Family Product Brief <sup>1</sup> |
| Reference<br>Manual | The Reference Manual contains a comprehensive description of the structure and function (operation) of a device.                 | KL25P80M48SF0RM <sup>1</sup>          |
| Data Sheet          | The Data Sheet includes electrical characteristics and signal connections.   | KL25P80M48SF0 <sup>1</sup>            |
| Chip Errata         | The chip mask set Errata provides additional or corrective information for a particular device mask set.                         | KINETIS_L_xN97F <sup>2</sup>          |
| Package             | Package dimensions are provided in package drawings.   | QFN 32-pin: 98ASA00473D1              |
| drawing             |  | QFN 48-pin: 98ASA00466D1              |
|                     |  | LQFP 64-pin: 98ASS23234W <sup>1</sup> |
|                     |  | LQFP 80-pin: 98ASS23174W <sup>1</sup> |

- 1. To find the associated resource, go to http://www.freescale.com and perform a search using this term.
- 2. To find the associated resource, go to <a href="http://www.freescale.com">http://www.freescale.com</a> and perform a search using this term with the "x" replaced by the revision of the device you are using.

Figure 1 shows the functional modules in the chip.



#### **Kinetis KL25 Family** ARM<sup>®</sup>Cortex™-M0+ System Memories and Clocks Core Memory Interfaces Phase-Internal locked loop watchdog Debug Program interfaces flash Frequency-DMA locked loop Interrupt **RAM** controller Low/high frequency oscillator **BME** MTB Internal reference clocks Security Human-Machine Analog **Timers** Communication and Integrity Interface (HMI) Interfaces 16-bit ADC **Timers** Internal 1x6ch+2x2ch х1 GPIOs watchdog $I^2C$ with х2 interrupt Analog comparator Low power timer x1 Low power x1 UART x1 TSI Periodic 6-bit DAC interrupt timers SPI х2 12-bit DAC **RTC UART** USB LS/FS x1 Migration difference from KL15 family **LEGEND**

Figure 1. Functional block diagram



## **Table of Contents**

| 1 | Rati | ngs      |   | 5  |
|---|------|----------|---|----|
|   | 1.1  | Therma   | al handling ratings                         | 5  |
|   | 1.2  | Moistu   | re handling ratings                         | 5  |
|   | 1.3  | ESD ha   | andling ratings                             | 5  |
|   | 1.4  | Voltage  | e and current operating ratings             | 5  |
| 2 | Gen  | eral     |   | 6  |
|   | 2.1  | AC ele   | ctrical characteristics                     | 6  |
|   | 2.2  | Nonsw    | itching electrical specifications           | 7  |
|   |      | 2.2.1    | Voltage and current operating requirements  | 7  |
|   |      | 2.2.2    | LVD and POR operating requirements          | 7  |
|   |      | 2.2.3    | Voltage and current operating behaviors     | 8  |
|   |      | 2.2.4    | Power mode transition operating behaviors   | 9  |
|   |      | 2.2.5    | Power consumption operating behaviors       | 10 |
|   |      | 2.2.6    | EMC radiated emissions operating behaviors  | 16 |
|   |      | 2.2.7    | Designing with radiated emissions in mind   | 17 |
|   |      | 2.2.8    | Capacitance attributes                      | 17 |
|   | 2.3  | Switch   | ing specifications                          | 17 |
|   |      | 2.3.1    | Device clock specifications                 | 17 |
|   |      | 2.3.2    | General switching specifications            | 18 |
|   | 2.4  | Therma   | al specifications                           | 18 |
|   |      | 2.4.1    | Thermal operating requirements              | 18 |
|   |      | 2.4.2    | Thermal attributes                          | 19 |
| 3 | Peri | pheral o | operating requirements and behaviors        | 19 |
|   | 3.1  | Core m   | nodules                                     | 19 |
|   |      | 3.1.1    | SWD electricals                             | 19 |
|   | 3.2  | System   | n modules                                   | 21 |
|   | 3.3  | Clock r  | modules                                     | 21 |
|   |      | 3.3.1    | MCG specifications                          | 21 |
|   |      | 3.3.2    | Oscillator electrical specifications        | 23 |
|   | 3.4  | Memor    | ries and memory interfaces                  | 25 |
|   |      | 3.4.1    | Flash electrical specifications             | 25 |
|   | 3.5  | Securit  | ty and integrity modules                    | 27 |
|   | 3.6  | Analog   |   | 27 |
|   |      | 3.6.1    | ADC electrical specifications               | 27 |
|   |      | 3.6.2    | CMP and 6-bit DAC electrical specifications | 32 |

|   |      | 3.6.3     | 12-bit DAC electrical characteristics           | 33   |
|---|------|-----------|---|------|
|   | 3.7  | Timers    |   | 36   |
|   | 3.8  | Comm      | unication interfaces                            | . 36 |
|   |      | 3.8.1     | USB electrical specifications                   | . 36 |
|   |      | 3.8.2     | USB VREG electrical specifications              | . 37 |
|   |      | 3.8.3     | SPI switching specifications                    |      |
|   |      | 3.8.4     | Inter-Integrated Circuit Interface (I2C) timing | . 42 |
|   |      | 3.8.5     | UART  |      |
|   | 3.9  |           | n-machine interfaces (HMI)                      |      |
|   |      | 3.9.1     | TSI electrical specifications                   | . 43 |
| 4 | Dim  | ensions   | <u> </u>  | . 44 |
|   | 4.1  | Obtaini   | ing package dimensions                          | . 44 |
| 5 |      |           |   |      |
|   | 5.1  | KL25 S    | Signal Multiplexing and Pin Assignments         | 44   |
|   | 5.2  | KL25 p    | inouts  | 47   |
| 6 | Ord  | 0.1       | ırts  |      |
|   | 6.1  |           | nining valid orderable parts                    |      |
| 7 | Part | identific | cation  | 51   |
|   | 7.1  | Descrip   | otion   | 52   |
|   | 7.2  | Format    | <u> </u>  | . 52 |
|   | 7.3  | Fields.   |   | . 52 |
|   | 7.4  | Examp     | le  | 52   |
| 8 | Terr | minology  | y and guidelines                                | . 53 |
|   | 8.1  | Definiti  | on: Operating requirement                       | 53   |
|   | 8.2  |           | on: Operating behavior                          |      |
|   | 8.3  |           | on: Attribute                                   |      |
|   | 8.4  |           | on: Rating                                      |      |
|   | 8.5  |           | of exceeding a rating                           | . 54 |
|   | 8.6  | Relatio   | nship between ratings and operating             |      |
|   |      |           | ments   |      |
|   | 8.7  |           | nes for ratings and operating requirements      |      |
|   | 8.8  |           | on: Typical value                               |      |
|   | 8.9  | Typical   | value conditions                                | . 57 |
| 9 | Rev  | ision his | story   | 57   |



### 1 Ratings

### 1.1 Thermal handling ratings

Table 1. Thermal handling ratings

| Symbol           | Description                   | Min.        | Max. | Unit | Notes |
|------------------|-------------------------------|-------------|------|------|-------|
| T <sub>STG</sub> | Storage temperature           | <b>-</b> 55 | 150  | °C   | 1     |
| T <sub>SDR</sub> | Solder temperature, lead-free | _           | 260  | °C   | 2     |

- 1. Determined according to JEDEC Standard JESD22-A103, High Temperature Storage Life.
- 2. Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

## 1.2 Moisture handling ratings

Table 2. Moisture handling ratings

|   | Symbol | Description                | Min. | Max. | Unit | Notes |
|---|--------|----------------------------|------|------|------|-------|
| Ī | MSL    | Moisture sensitivity level | _    | 3    | _    | 1     |

 Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

#### 1.3 ESD handling ratings

Table 3. ESD handling ratings

| Symbol           | Description   | Min.  | Max.  | Unit | Notes |
|------------------|---|-------|-------|------|-------|
| V <sub>HBM</sub> | Electrostatic discharge voltage, human body model     | -2000 | +2000 | V    | 1     |
| V <sub>CDM</sub> | Electrostatic discharge voltage, charged-device model | -500  | +500  | V    | 2     |
| I <sub>LAT</sub> | Latch-up current at ambient temperature of 105 °C     | -100  | +100  | mA   | 3     |

- 1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
- 2. Determined according to JEDEC Standard JESD22-C101, Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components.
- 3. Determined according to JEDEC Standard JESD78, IC Latch-Up Test.



### 1.4 Voltage and current operating ratings

Table 4. Voltage and current operating ratings

| Symbol              | Description   | Min.                  | Max.                  | Unit |
|---------------------|---|-----------------------|-----------------------|------|
| $V_{DD}$            | Digital supply voltage  | -0.3                  | 3.8                   | V    |
| I <sub>DD</sub>     | Digital supply current  | _                     | 120                   | mA   |
| V <sub>IO</sub>     | IO pin input voltage  | -0.3                  | V <sub>DD</sub> + 0.3 | V    |
| I <sub>D</sub>      | Instantaneous maximum current single pin limit (applies to all port pins) | -25                   | 25                    | mA   |
| $V_{DDA}$           | Analog supply voltage   | V <sub>DD</sub> – 0.3 | V <sub>DD</sub> + 0.3 | V    |
| V <sub>USB_DP</sub> | USB_DP input voltage  | -0.3                  | 3.63                  | V    |
| V <sub>USB_DM</sub> | USB_DM input voltage  | -0.3                  | 3.63                  | V    |
| V <sub>REGIN</sub>  | USB regulator input   | -0.3                  | 6.0                   | V    |

#### 2 General

#### 2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.

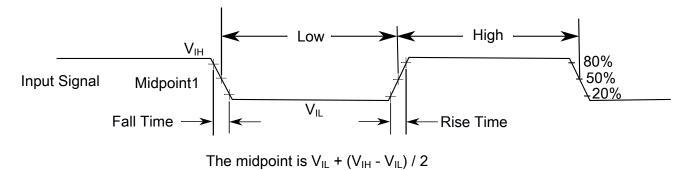


Figure 2. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assume the output pins have the following characteristics.

- $C_L = 30 pF loads$
- Slew rate disabled
- Normal drive strength



#### 2.2 Nonswitching electrical specifications

#### 2.2.1 Voltage and current operating requirements

Table 5. Voltage and current operating requirements

| Symbol                             | Description  | Min.                   | Max.                 | Unit | Notes |
|------------------------------------|--|------------------------|----------------------|------|-------|
| V <sub>DD</sub>                    | Supply voltage   | 1.71                   | 3.6                  | V    |       |
| V <sub>DDA</sub>                   | Analog supply voltage  | 1.71                   | 3.6                  | V    | _     |
| $V_{DD} - V_{DDA}$                 | V <sub>DD</sub> -to-V <sub>DDA</sub> differential voltage  | -0.1                   | 0.1                  | V    | _     |
| V <sub>SS</sub> – V <sub>SSA</sub> | V <sub>SS</sub> -to-V <sub>SSA</sub> differential voltage  | -0.1                   | 0.1                  | V    | _     |
| V <sub>IH</sub>                    | Input high voltage   |                        |                      |      | _     |
|                                    | • 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | $0.7 \times V_{DD}$    | _                    | V    |       |
|                                    | • 1.7 V ≤ V <sub>DD</sub> ≤ 2.7 V  | $0.75 \times V_{DD}$   | _                    | V    |       |
| V <sub>IL</sub>                    | Input low voltage  |                        |                      |      | _     |
|                                    | • 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | _                      | $0.35 \times V_{DD}$ | V    |       |
|                                    | • 1.7 V ≤ V <sub>DD</sub> ≤ 2.7 V  | _                      | $0.3 \times V_{DD}$  | V    |       |
| V <sub>HYS</sub>                   | Input hysteresis   | 0.06 × V <sub>DD</sub> | _                    | V    | _     |
| licio                              | IO pin negative DC injection current—single pin  • V <sub>IN</sub> < V <sub>SS</sub> =0.3V   | -3                     | _                    | mA   | 1     |
| I <sub>ICcont</sub>                | Contiguous pin DC injection current —regional limit, includes sum of negative injection currents of 16 contiguous pins  • Negative current injection | -25                    | _                    | mA   | _     |
| V <sub>ODPU</sub>                  | Open drain pullup voltage level  | V <sub>DD</sub>        | V <sub>DD</sub>      | V    | 2     |
| V <sub>RAM</sub>                   | V <sub>DD</sub> voltage required to retain RAM   | 1.2                    | _                    | V    | _     |

<sup>1.</sup> All I/O pins are internally clamped to  $V_{SS}$  through a ESD protection diode. There is no diode connection to  $V_{DD}$ . If  $V_{IN}$  greater than  $V_{IO\_MIN}$  (=  $V_{SS}$ -0.3 V) is observed, then there is no need to provide current limiting resistors at the pads. If this limit cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as R =  $(V_{IO\_MIN} - V_{IN})/|I_{ICIO}|$ .

## 2.2.2 LVD and POR operating requirements

Table 6. V<sub>DD</sub> supply LVD and POR operating requirements

| Symbol           | Description                                | Min. | Тур. | Max. | Unit | Notes |
|------------------|--|------|------|------|------|-------|
| V <sub>POR</sub> | Falling V <sub>DD</sub> POR detect voltage | 0.8  | 1.1  | 1.5  | V    | _     |

<sup>2.</sup> Open drain outputs must be pulled to  $V_{DD}$ .



Table 6. V<sub>DD</sub> supply LVD and POR operating requirements (continued)

| Symbol             | Description   | Min. | Тур. | Max. | Unit | Notes |
|--------------------|---|------|------|------|------|-------|
| $V_{LVDH}$         | Falling low-voltage detect threshold — high range (LVDV = 01) | 2.48 | 2.56 | 2.64 | V    | _     |
|                    | Low-voltage warning thresholds — high range                   |      |      |      |      | 1     |
| $V_{\text{LVW1H}}$ | • Level 1 falling (LVWV = 00)                                 | 2.62 | 2.70 | 2.78 | V    |       |
| $V_{LVW2H}$        | • Level 2 falling (LVWV = 01)                                 | 2.72 | 2.80 | 2.88 | V    |       |
| $V_{LVW3H}$        | • Level 3 falling (LVWV = 10)                                 | 2.82 | 2.90 | 2.98 | V    |       |
| $V_{LVW4H}$        | Level 4 falling (LVWV = 11)                                   | 2.92 | 3.00 | 3.08 | V    |       |
| V <sub>HYSH</sub>  | Low-voltage inhibit reset/recover hysteresis — high range     | _    | ±60  | _    | mV   | _     |
| $V_{LVDL}$         | Falling low-voltage detect threshold — low range (LVDV=00)    | 1.54 | 1.60 | 1.66 | V    | _     |
|                    | Low-voltage warning thresholds — low range                    |      |      |      |      | 1     |
| $V_{LVW1L}$        | • Level 1 falling (LVWV = 00)                                 | 1.74 | 1.80 | 1.86 | V    |       |
| $V_{\text{LVW2L}}$ | • Level 2 falling (LVWV = 01)                                 | 1.84 | 1.90 | 1.96 | V    |       |
| $V_{\text{LVW3L}}$ | • Level 3 falling (LVWV = 10)                                 | 1.94 | 2.00 | 2.06 | V    |       |
| $V_{\text{LVW4L}}$ | • Level 4 falling (LVWV = 11)                                 | 2.04 | 2.10 | 2.16 | V    |       |
| V <sub>HYSL</sub>  | Low-voltage inhibit reset/recover hysteresis — low range      | _    | ±40  | _    | mV   | _     |
| $V_{BG}$           | Bandgap voltage reference                                     | 0.97 | 1.00 | 1.03 | V    | _     |
| t <sub>LPO</sub>   | Internal low power oscillator period — factory trimmed        | 900  | 1000 | 1100 | μs   | _     |

<sup>1.</sup> Rising thresholds are falling threshold + hysteresis voltage

## 2.2.3 Voltage and current operating behaviors

Table 7. Voltage and current operating behaviors

| Symbol           | Description   | Min.                  | Max. | Unit | Notes |
|------------------|---|-----------------------|------|------|-------|
| V <sub>OH</sub>  | Output high voltage — Normal drive pad (except RESET)                                 |                       |      |      | 1, 2  |
|                  | • 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V, I <sub>OH</sub> = −5 mA                            | V <sub>DD</sub> – 0.5 | _    | V    |       |
|                  | • 1.71 V ≤ V <sub>DD</sub> ≤ 2.7 V, I <sub>OH</sub> = −1.5 mA                         | V <sub>DD</sub> – 0.5 | _    | V    |       |
| V <sub>OH</sub>  | Output high voltage — High drive pad (except RESET)                                   |                       |      |      | 1, 2  |
|                  | • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}, \text{I}_{OH} = -18 \text{ mA}$ | $V_{DD} - 0.5$        | _    | V    |       |
|                  | • 1.71 V ≤ V <sub>DD</sub> ≤ 2.7 V, I <sub>OH</sub> = −6 mA                           | V <sub>DD</sub> – 0.5 | _    | V    |       |
| I <sub>OHT</sub> | Output high current total for all ports   | _                     | 100  | mA   | _     |



| Symbol           | Description  | Min. | Max.  | Unit | Notes |
|------------------|--|------|-------|------|-------|
| V <sub>OL</sub>  | Output low voltage — Normal drive pad  |      |       |      | 1     |
|                  | • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}, \text{I}_{OL} = 5 \text{ mA}$    | _    | 0.5   | V    |       |
|                  | • $1.71 \text{ V} \le \text{V}_{DD} \le 2.7 \text{ V}, \text{I}_{OL} = 1.5 \text{ mA}$ | _    | 0.5   | V    |       |
| V <sub>OL</sub>  | Output low voltage — High drive pad  |      |       |      | 1     |
|                  | • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}, \text{I}_{OL} = 18 \text{ mA}$   | _    | 0.5   | V    |       |
|                  | • $1.71 \text{ V} \le \text{V}_{DD} \le 2.7 \text{ V}, \text{I}_{OL} = 6 \text{ mA}$   | _    | 0.5   | V    |       |
| I <sub>OLT</sub> | Output low current total for all ports   | _    | 100   | mA   | _     |
| I <sub>IN</sub>  | Input leakage current (per pin) for full temperature range                             | _    | 1     | μА   | 3     |
| I <sub>IN</sub>  | Input leakage current (per pin) at 25 °C   | _    | 0.025 | μΑ   | 3     |
| I <sub>IN</sub>  | Input leakage current (total all pins) for full temperature range                      | _    | 65    | μА   | 3     |
| l <sub>OZ</sub>  | Hi-Z (off-state) leakage current (per pin)   | _    | 1     | μA   | _     |
| _                |  |      |       |      |       |

20

20

50

50

kΩ

kΩ

Table 7. Voltage and current operating behaviors (continued)

 $R_{PU}$ 

R<sub>PD</sub>

Internal pullup resistors

Internal pulldown resistors

#### 2.2.4 Power mode transition operating behaviors

All specifications except  $t_{POR}$  and VLLSx $\rightarrow$ RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 48 MHz
- Bus and flash clock = 24 MHz
- FEI clock mode

POR and VLLSx→RUN recovery use FEI clock mode at the default CPU and system frequency of 21 MHz, and a bus and flash clock frequency of 10.5 MHz.

Table 8. Power mode transition operating behaviors

| Symbol           | Description  | Min. | Тур. | Max. | Unit |   |
|------------------|--|------|------|------|------|---|
| t <sub>POR</sub> | After a POR event, amount of time from the point V <sub>DD</sub> reaches 1.8 V to execution of the first | _    | _    | 300  | μs   | 1 |

<sup>1.</sup> PTB0, PTB1, PTD6, and PTD7 I/O have both high drive and normal drive capability selected by the associated PTx\_PCRn[DSE] control bit. All other GPIOs are normal drive only.

<sup>2.</sup> The reset pin only contains an active pull down device when configured as the RESET signal or as a GPIO. When configured as a GPIO output, it acts as a pseudo open drain output.

<sup>3.</sup> Measured at V<sub>DD</sub> = 3.6 V

<sup>4.</sup> Measured at  $V_{DD}$  supply voltage =  $V_{DD}$  min and Vinput =  $V_{SS}$ 

<sup>5.</sup> Measured at VDD supply voltage = VDD min and Vinput = VDD



Table 8. Power mode transition operating behaviors (continued)

| Symbol | Description   | Min. | Тур. | Max. | Unit |  |
|--------|---|------|------|------|------|--|
|        | instruction across the operating temperature range of the chip. |      |      |      |      |  |
|        | • VLLS0 → RUN   | _    | 95   | 115  | μs   |  |
|        | • VLLS1 → RUN   | _    | 93   | 115  | μs   |  |
|        | VLLS3 → RUN   | _    | 42   | 53   | μs   |  |
|        | • LLS → RUN   | _    | 4    | 4.6  | μs   |  |
|        | • VLPS → RUN  | _    | 4    | 4.4  | μs   |  |
|        | • STOP → RUN  | _    | 4    | 4.4  | μs   |  |

<sup>1.</sup> Normal boot (FTFA\_FOPT[LPBOOT]=11).

#### 2.2.5 Power consumption operating behaviors

The maximum values stated in the following table represent characterized results equivalent to the mean plus three times the standard deviation (mean + 3 sigma).

Table 9. Power consumption operating behaviors

| Symbol                    | Description   | Temp.        | Тур. | Max      | Unit | Note |
|---------------------------|---|--------------|------|----------|------|------|
| I <sub>DDA</sub>          | Analog supply current   | <del>_</del> | _    | See note | mA   | 1    |
| I <sub>DD_RUNCO_</sub> CM | Run mode current in compute operation - 48 MHz core / 24 MHz flash/ bus disabled, LPTMR running using 4 MHz internal reference clock, CoreMark® benchmark code executing from flash, at 3.0 V | _            | 6.4  |          | mA   | 2    |
| I <sub>DD_RUNCO</sub>     | Run mode current in compute operation - 48 MHz core / 24 MHz flash / bus clock disabled, code of while(1) loop executing from flash, at 3.0 V   | _            | 3.9  | 4.8      | mA   | 3    |
| I <sub>DD_RUN</sub>       | Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks disabled, code executing from flash, at 3.0 V  | _            | 5    | 5.9      | mA   | 3    |



Table 9. Power consumption operating behaviors (continued)

| Symbol                 | Description   | Temp.     | Тур. | Max   | Unit | Note |
|------------------------|---|-----------|------|-------|------|------|
| I <sub>DD_RUN</sub>    | Run mode current - 48 MHz core / 24   | at 25 °C  | 6.2  | 6.5   | mA   | 3, 4 |
|                        | MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 3.0 V   | at 125 °C | 6.8  | 7.1   | mA   |      |
| I <sub>DD_WAIT</sub>   | Wait mode current - core disabled / 48<br>MHz system / 24 MHz bus / flash<br>disabled (flash doze enabled), all<br>peripheral clocks disabled, at 3.0 V   | _         | 3.1  | 3.8   | mA   | 3    |
| I <sub>DD_WAIT</sub>   | Wait mode current - core disabled / 24<br>MHz system / 24 MHz bus / flash<br>disabled (flash doze enabled), all<br>peripheral clocks disabled • at 3.0 V  | _         | 2.4  | 3.2   | mA   | 3    |
| I <sub>DD_PSTOP2</sub> | Stop mode current with partial stop 2 clocking option - core and system disabled / 10.5 MHz bus, at 3.0 V   | _         | 1.6  | 2     | mA   | 3    |
| DD_VLPRCO _CM          | Very-low-power run mode current in compute operation - 4 MHz core / 0.8 MHz flash / bus clock disabled, LPTMR running with 4 MHz internal reference clock, CoreMark benchmark code executing from flash, at 3.0 V |           | 777  |       | μА   | 5    |
| I <sub>DD_VLPRCO</sub> | Very low power run mode current in compute operation - 4 MHz core / 0.8 MHz flash / bus clock disabled, code executing from flash, at 3.0 V   | _         | 171  | 420   | μА   | 6    |
| I <sub>DD_VLPR</sub>   | Very low power run mode current - 4<br>MHz core / 0.8 MHz bus and flash, all<br>peripheral clocks disabled, code<br>executing from flash, at 3.0 V  | _         | 204  | 449   | μA   | 6    |
| I <sub>DD_VLPR</sub>   | Very low power run mode current - 4<br>MHz core / 0.8 MHz bus and flash, all<br>peripheral clocks enabled, code<br>executing from flash, at 3.0 V   | _         | 262  | 509   | μА   | 4, 6 |
| I <sub>DD_VLPW</sub>   | Very low power wait mode current -<br>core disabled / 4 MHz system / 0.8<br>MHz bus / flash disabled (flash doze<br>enabled), all peripheral clocks disabled,<br>at 3.0 V   | _         | 123  | 366   | μА   | 6    |
| I <sub>DD_STOP</sub>   | Stop mode current at 3.0 V  | at 25 °C  | 319  | 343   | μA   | _    |
|                        |   | at 50 °C  | 333  | 365   | μA   |      |
|                        |   | at 70 °C  | 353  | 400   | μA   |      |
|                        |   | at 85 °C  | 380  | 450   | μA   |      |
|                        |   | at 105 °C | 444  | 572   | μA   |      |
| I <sub>DD_VLPS</sub>   | Very-low-power stop mode current at   | at 25 °C  | 3.75 | 8.46  | μA   | _    |
|                        | 3.0 V   | at 50 °C  | 6.66 | 13.41 | μA   |      |
|                        |   | at 70 °C  | 12.9 | 25.71 | μA   | 1    |



Table 9. Power consumption operating behaviors (continued)

| Symbol                | Description                                   | Temp.     | Тур.  | Max   | Unit | Note |
|-----------------------|---|-----------|-------|-------|------|------|
|                       |   | at 85 °C  | 22.7  | 44.06 | μA   |      |
|                       |   | at 105 °C | 48.4  | 90.1  | μA   |      |
| I <sub>DD_LLS</sub>   | Low leakage stop mode current at 3.0          | at 25 °C  | 1.68  | 2.09  | μA   | _    |
|                       | V   | at 50 °C  | 3.05  | 4.04  | μA   |      |
|                       |   | at 70 °C  | 5.71  | 7.75  | μA   |      |
|                       |   | at 85 °C  | 10    | 13.54 | μA   |      |
|                       |   | at 105 °C | 22.4  | 30.41 | μA   |      |
| I <sub>DD_VLLS3</sub> | Very low-leakage stop mode 3 current          | at 25 °C  | 1.22  | 1.6   | μA   | _    |
|                       | at 3.0 V                                      | at 50 °C  | 2.25  | 2.31  | μA   |      |
|                       |   | at 70 °C  | 4.21  | 5.44  | μΑ   |      |
|                       |   | at 85 °C  | 7.37  | 9.44  | μΑ   |      |
|                       |   | at 105 °C | 16.6  | 21.76 | μA   |      |
| I <sub>DD_VLLS1</sub> | Very low-leakage stop mode 1 current at 3.0 V | at 25 °C  | 0.58  | 0.94  | μΑ   | _    |
|                       |   | at 50 °C  | 1.26  | 1.31  | μΑ   |      |
|                       |   | at 70 °C  | 2.53  | 3.33  | μΑ   |      |
|                       |   | at 85 °C  | 4.74  | 6.1   | μΑ   |      |
|                       |   | at 105 °C | 11.4  | 15.27 | μΑ   |      |
| I <sub>DD_VLLS0</sub> | Very low-leakage stop mode 0 current          | at 25 °C  | 0.31  | 0.65  | μΑ   | _    |
|                       | (SMC_STOPCTRL[PORPO] = 0) at 3.0              | at 50 °C  | 0.99  | 1.43  | μΑ   |      |
|                       | ľ   | at 70 °C  | 2.25  | 3.01  | μΑ   |      |
|                       |   | at 85 °C  | 4.46  | 5.83  | μΑ   |      |
|                       |   | at 105 °C | 11.13 | 14.99 | μΑ   |      |
| I <sub>DD_VLLS0</sub> | Very low-leakage stop mode 0 current          | at 25 °C  | 0.12  | 0.47  | μΑ   | 7    |
|                       | (SMC_STOPCTRL[PORPO] = 1) at 3.0              | at 50 °C  | 0.8   | 1.24  | μΑ   |      |
|                       | v   | at 70 °C  | 2.06  | 2.81  | μΑ   |      |
|                       |   | at 85 °C  | 4.27  | 5.62  | μA   |      |
|                       |   | at 105 °C | 10.93 | 14.78 | μA   |      |

<sup>1.</sup> The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.

<sup>2.</sup> MCG configured for PEE mode. CoreMark benchmark compiled using Keil 4.54 with optimization level 3, optimized for time.

<sup>3.</sup> MCG configured for FEI mode.

<sup>4.</sup> Incremental current consumption from peripheral activity is not included.

<sup>5.</sup> MCG configured for BLPI mode. CoreMark benchmark compiled using IAR 6.40 with optimization level high, optimized for balanced.

<sup>6.</sup> MCG configured for BLPI mode.

<sup>7.</sup> No brownout.



Table 10. Low power mode peripheral adders — typical value

| Symbol                     | Description   |   |     | Т   | empera | ature (° | C)  |     | Unit |
|----------------------------|---|---|-----|-----|--------|----------|-----|-----|------|
|                            |   |   | -40 | 25  | 50     | 70       | 85  | 105 |      |
| lirefsten4mHz              | 4 MHz internal reference clock<br>Measured by entering STOP of<br>with 4 MHz IRC enabled.   |   | 56  | 56  | 56     | 56       | 56  | 56  | μΑ   |
| IREFSTEN32KHz              | 32 kHz internal reference cloc<br>Measured by entering STOP r<br>32 kHz IRC enabled.  |   | 52  | 52  | 52     | 52       | 52  | 52  | μA   |
| I <sub>EREFSTEN4MHz</sub>  | External 4 MHz crystal clock adder.  Measured by entering STOP or VLPS mode with the crystal enabled.   |   | 206 | 228 | 237    | 245      | 251 | 258 | μA   |
| I <sub>EREFSTEN32KHz</sub> | External 32 kHz crystal clock   | VLLS1   | 440 | 490 | 540    | 560      | 570 | 580 | nA   |
|                            | adder by means of the OSC0_CR[EREFSTEN and  | VLLS3   | 440 | 490 | 540    | 560      | 570 | 580 |      |
|                            | EREFSTEN] bits. Measured  | LLS   | 490 | 490 | 540    | 560      | 570 | 680 |      |
|                            | by entering all modes with  | VLPS  | 510 | 560 | 560    | 560      | 610 | 680 |      |
|                            | the crystal enabled.  | STOP  | 510 | 560 | 560    | 560      | 610 | 680 |      |
| I <sub>CMP</sub>           | CMP peripheral adder measured by placing the device in VLLS1 mode with CMP enabled using the 6-bit DAC and a single external input for compare. Includes 6-bit DAC power consumption.         |   | 22  | 22  | 22     | 22       | 22  | 22  | μА   |
| I <sub>RTC</sub>           | RTC peripheral adder measur<br>the device in VLLS1 mode wit<br>kHz crystal enabled by means<br>RTC_CR[OSCE] bit and the F<br>set for 1 minute. Includes ERC<br>kHz external crystal) power co | h external 32<br>of the<br>RTC ALARM<br>CLK32K (32    | 432 | 357 | 388    | 475      | 532 | 810 | nA   |
| luart                      | UART peripheral adder<br>measured by placing the<br>device in STOP or VLPS<br>mode with selected clock<br>source waiting for RX data at   | MCGIRCLK<br>(4 MHz<br>internal<br>reference<br>clock) | 66  | 66  | 66     | 66       | 66  | 66  | μА   |
|                            | 115200 baud rate. Includes selected clock source power consumption.   | OSCERCLK<br>(4 MHz<br>external<br>crystal)            | 214 | 237 | 246    | 254      | 260 | 268 |      |
| I <sub>TPM</sub>           | TPM peripheral adder measured by placing the device in STOP or VLPS mode with selected clock source configured for output   | MCGIRCLK<br>(4 MHz<br>internal<br>reference<br>clock) | 86  | 86  | 86     | 86       | 86  | 86  | μА   |
|                            | source configured for output compare generating 100 Hz clock signal. No load is placed on the I/O generating the clock signal. Includes selected clock source and I/O switching currents.     | OSCERCLK<br>(4 MHz<br>external<br>crystal)            | 235 | 256 | 265    | 274      | 280 | 287 |      |



Table 10. Low power mode peripheral adders — typical value (continued)

| Symbol           | Description  | Temperature (°C) |     |     |     |     |     | Unit |
|------------------|--|------------------|-----|-----|-----|-----|-----|------|
|                  |  | -40              | 25  | 50  | 70  | 85  | 105 |      |
| I <sub>BG</sub>  | Bandgap adder when BGEN bit is set and device is placed in VLPx, LLS, or VLLSx mode.   | 45               | 45  | 45  | 45  | 45  | 45  | μΑ   |
| I <sub>ADC</sub> | ADC peripheral adder combining the measured values at V <sub>DD</sub> and V <sub>DDA</sub> by placing the device in STOP or VLPS mode. ADC is configured for low power mode using the internal clock and continuous conversions. | 366              | 366 | 366 | 366 | 366 | 366 | μА   |

#### 2.2.5.1 Diagram: Typical IDD\_RUN operating behavior

The following data was measured under these conditions:

- MCG in FBE for run mode, and BLPE for VLPR mode
- USB regulator disabled
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFA



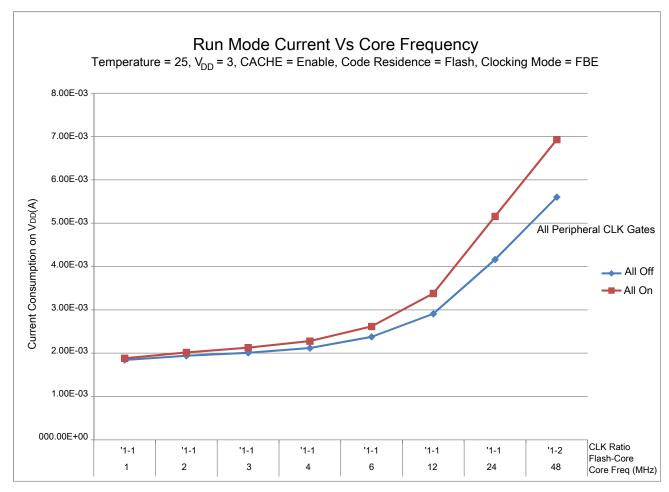


Figure 3. Run mode supply current vs. core frequency



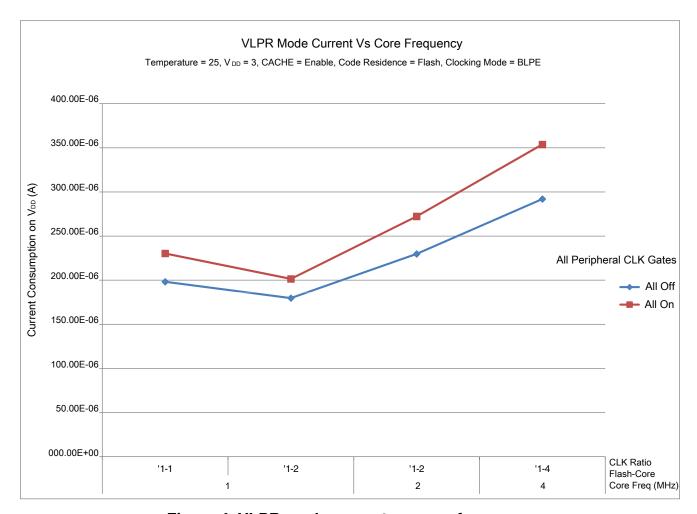


Figure 4. VLPR mode current vs. core frequency

#### 2.2.6 EMC radiated emissions operating behaviors

Table 11. EMC radiated emissions operating behaviors for 64-pin LQFP package

| Symbol              | Description                        | Frequency<br>band<br>(MHz) | Тур. | Unit | Notes |
|---------------------|------------------------------------|----------------------------|------|------|-------|
| V <sub>RE1</sub>    | Radiated emissions voltage, band 1 | 0.15–50                    | 13   | dΒμV | 1, 2  |
| V <sub>RE2</sub>    | Radiated emissions voltage, band 2 | 50–150                     | 15   | dΒμV |       |
| V <sub>RE3</sub>    | Radiated emissions voltage, band 3 | 150–500                    | 12   | dΒμV |       |
| V <sub>RE4</sub>    | Radiated emissions voltage, band 4 | 500-1000                   | 7    | dΒμV |       |
| V <sub>RE_IEC</sub> | IEC level                          | 0.15–1000                  | М    |      | 2, 3  |

<sup>1.</sup> Determined according to IEC Standard 61967-1, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions and IEC Standard 61967-2, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and



Wideband TEM Cell Method. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.

- 2.  $V_{DD} = 3.3 \text{ V}$ ,  $T_A = 25 \,^{\circ}\text{C}$ ,  $f_{OSC} = 8 \,^{\circ}\text{MHz}$  (crystal),  $f_{SYS} = 48 \,^{\circ}\text{MHz}$ ,  $f_{BUS} = 48 \,^{\circ}\text{MHz}$
- 3. Specified according to Annex D of IEC Standard 61967-2, Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method

#### 2.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

- 1. Go to www.freescale.com.
- 2. Perform a keyword search for "EMC design."

#### 2.2.8 Capacitance attributes

Table 12. Capacitance attributes

| Symbol          | Description       | Min. | Max. | Unit |
|-----------------|-------------------|------|------|------|
| C <sub>IN</sub> | Input capacitance |      | 7    | pF   |

### 2.3 Switching specifications

#### 2.3.1 Device clock specifications

Table 13. Device clock specifications

| Symbol               | Description  | Min. | Max. | Unit |
|----------------------|--|------|------|------|
|                      | Normal run mode  | •    |      |      |
| f <sub>SYS</sub>     | System and core clock                                  | _    | 48   | MHz  |
| f <sub>BUS</sub>     | Bus clock  | _    | 24   | MHz  |
| f <sub>FLASH</sub>   | Flash clock  | _    | 24   | MHz  |
| f <sub>SYS_USB</sub> | System and core clock when Full Speed USB in operation | 20   | _    | MHz  |
| f <sub>LPTMR</sub>   | LPTMR clock  | _    | 24   | MHz  |
|                      | VLPR and VLPS modes <sup>1</sup>                       |      |      |      |
| f <sub>SYS</sub>     | System and core clock                                  | _    | 4    | MHz  |
| f <sub>BUS</sub>     | Bus clock  | _    | 1    | MHz  |
| f <sub>FLASH</sub>   | Flash clock  | _    | 1    | MHz  |
| f <sub>LPTMR</sub>   | LPTMR clock <sup>2</sup>                               | _    | 24   | MHz  |



Table 13. Device clock specifications (continued)

| Symbol                   | Description   | Min. | Max. | Unit |
|--------------------------|---|------|------|------|
| f <sub>ERCLK</sub>       | External reference clock  | _    | 16   | MHz  |
| f <sub>LPTMR_ERCLK</sub> | LPTMR external reference clock  | _    | 16   | MHz  |
| f <sub>osc_hi_2</sub>    | Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x) | _    | 16   | MHz  |
| f <sub>TPM</sub>         | TPM asynchronous clock  | _    | 8    | MHz  |
| f <sub>UART0</sub>       | UART0 asynchronous clock  | _    | 8    | MHz  |

The frequency limitations in VLPR and VLPS modes here override any frequency specification listed in the timing specification for any other module. These same frequency limits apply to VLPS, whether VLPS was entered from RUN or from VLPR.

#### 2.3.2 General switching specifications

These general-purpose specifications apply to all signals configured for GPIO and UART signals.

Table 14. General switching specifications

| Description  | Min. | Max. | Unit                | Notes |
|--|------|------|---------------------|-------|
| GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path | 1.5  | _    | Bus clock<br>cycles | 1     |
| External RESET and NMI pin interrupt pulse width — Asynchronous path               | 100  | _    | ns                  | 2     |
| GPIO pin interrupt pulse width — Asynchronous path                                 | 16   | _    | ns                  | 2     |
| Port rise and fall time  | _    | 36   | ns                  | 3     |

<sup>1.</sup> The greater synchronous and asynchronous timing must be met.

### 2.4 Thermal specifications

### 2.4.1 Thermal operating requirements

Table 15. Thermal operating requirements

| Symbol         | Description              | Min. | Max. | Unit |
|----------------|--------------------------|------|------|------|
| T <sub>J</sub> | Die junction temperature | -40  | 125  | °C   |
| T <sub>A</sub> | Ambient temperature      | -40  | 105  | °C   |

<sup>2.</sup> The LPTMR can be clocked at this speed in VLPR or VLPS only when the source is an external pin.

<sup>2.</sup> This is the shortest pulse that is guaranteed to be recognized.

<sup>3. 75</sup> pF load



#### 2.4.2 Thermal attributes

Table 16. Thermal attributes

| Board type        | Symbol            | Description   | 80<br>LQFP | 64<br>LQFP | 48 QFN | 32 QFN | Unit | Notes |
|-------------------|-------------------|---|------------|------------|--------|--------|------|-------|
| Single-layer (1S) | $R_{\theta JA}$   | Thermal resistance, junction to ambient (natural convection)                                    | 70         | 71         | 84     | 92     | °C/W | 1     |
| Four-layer (2s2p) | $R_{\theta JA}$   | Thermal resistance, junction to ambient (natural convection)                                    | 53         | 52         | 28     | 33     | °C/W |       |
| Single-layer (1S) | R <sub>θЈМА</sub> | Thermal resistance, junction to ambient (200 ft./min. air speed)                                | _          | 59         | 69     | 75     | °C/W |       |
| Four-layer (2s2p) | R <sub>θЈМА</sub> | Thermal resistance, junction to ambient (200 ft./min. air speed)                                | _          | 46         | 22     | 27     | °C/W |       |
| _                 | R <sub>0JB</sub>  | Thermal resistance, junction to board   | 34         | 34         | 10     | 12     | °C/W | 2     |
|                   | R <sub>θJC</sub>  | Thermal resistance, junction to case  | 15         | 20         | 2.0    | 1.8    | °C/W | 3     |
| _                 | $\Psi_{ m JT}$    | Thermal characterization parameter, junction to package top outside center (natural convection) | 0.6        | 5          | 5.0    | 8      | °C/W | 4     |

- 1. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air), or EIA/JEDEC Standard JESD51-6, Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air).
- 2. Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board*.
- 3. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
- 4. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air).

## 3 Peripheral operating requirements and behaviors

#### 3.1 Core modules



#### 3.1.1 SWD electricals

Table 17. SWD full voltage range electricals

| Symbol | Description                                     | Min. | Max. | Unit |
|--------|---|------|------|------|
|        | Operating voltage                               | 1.71 | 3.6  | V    |
| J1     | SWD_CLK frequency of operation                  |      |      |      |
|        | Serial wire debug                               | 0    | 25   | MHz  |
| J2     | SWD_CLK cycle period                            | 1/J1 | _    | ns   |
| J3     | SWD_CLK clock pulse width                       |      |      |      |
|        | Serial wire debug                               | 20   | _    | ns   |
| J4     | SWD_CLK rise and fall times                     | _    | 3    | ns   |
| J9     | SWD_DIO input data setup time to SWD_CLK rise   | 10   | _    | ns   |
| J10    | SWD_DIO input data hold time after SWD_CLK rise | 0    | _    | ns   |
| J11    | SWD_CLK high to SWD_DIO data valid              | _    | 32   | ns   |
| J12    | SWD_CLK high to SWD_DIO high-Z                  | 5    | _    | ns   |

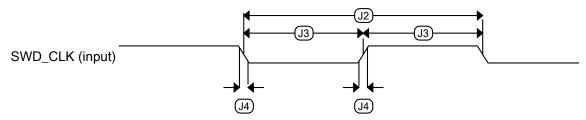


Figure 5. Serial wire clock input timing



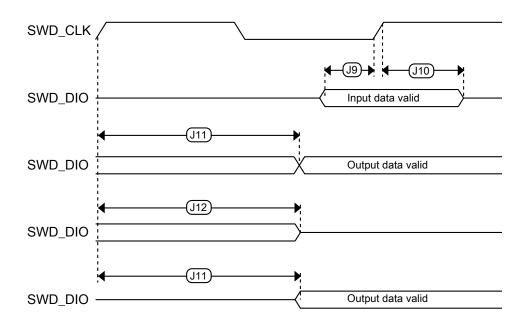


Figure 6. Serial wire data timing

## 3.2 System modules

There are no specifications necessary for the device's system modules.

#### 3.3 Clock modules

### 3.3.1 MCG specifications

Table 18. MCG specifications

| Symbol                  | Description  | Min.  | Тур.   | Max.    | Unit              | Notes |
|-------------------------|--|-------|--------|---------|-------------------|-------|
| f <sub>ints_ft</sub>    | Internal reference frequency (slow clock) — factory trimmed at nominal V <sub>DD</sub> and 25 °C                       | _     | 32.768 | _       | kHz               |       |
| f <sub>ints_t</sub>     | Internal reference frequency (slow clock) — user trimmed   | 31.25 | _      | 39.0625 | kHz               |       |
| $\Delta_{fdco\_res\_t}$ | Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using C3[SCTRIM] and C4[SCFTRIM] | _     | ± 0.3  | ± 0.6   | %f <sub>dco</sub> | 1     |



Table 18. MCG specifications (continued)

| Symbol                   | Description  |   | Min.                            | Тур.      | Max.                  | Unit              | Notes |
|--------------------------|--|---|---------------------------------|-----------|-----------------------|-------------------|-------|
| $\Delta f_{dco\_t}$      |  | trimmed average DCO output<br>ltage and temperature   | _                               | +0.5/-0.7 | ± 3                   | %f <sub>dco</sub> | 1, 2  |
| $\Delta f_{dco\_t}$      | Total deviation of frequency over fix range of 0–70 °C   | _   | ± 0.4                           | ± 1.5     | %f <sub>dco</sub>     | 1, 2              |       |
| f <sub>intf_ft</sub>     | Internal reference factory trimmed a   | _   | 4                               | _         | MHz                   |                   |       |
| Δf <sub>intf_ft</sub>    | Frequency deviati<br>(fast clock) over to<br>factory trimmed a   | _   | +1/-2                           | ± 3       | %f <sub>intf_ft</sub> | 2                 |       |
| f <sub>intf_t</sub>      |  | Internal reference frequency (fast clock) — user trimmed at nominal V <sub>DD</sub> and 25 °C |                                 |           | 5                     | MHz               |       |
| f <sub>loc_low</sub>     | Loss of external of RANGE = 00   | (3/5) x<br>f <sub>ints_t</sub>  | _                               | _         | kHz                   |                   |       |
| f <sub>loc_high</sub>    | Loss of external of RANGE = 01, 10,  | lock minimum frequency — or 11  | (16/5) x<br>f <sub>ints_t</sub> | _         | _                     | kHz               |       |
|                          | ı  | FL  | L                               |           | '                     |                   |       |
| f <sub>fII_ref</sub>     | FLL reference free   | quency range  | 31.25                           | _         | 39.0625               | kHz               |       |
| f <sub>dco</sub>         | DCO output frequency range   | Low range (DRS = 00) $640 \times f_{\text{fll\_ref}}$   | 20                              | 20.97     | 25                    | MHz               | 3, 4  |
|                          |  | Mid range (DRS = 01) $1280 \times f_{fil} \text{ ref}$  | 40                              | 41.94     | 48                    | MHz               |       |
| f <sub>dco_t_DMX3</sub>  | DCO output frequency   | Low range (DRS = 00)<br>$732 \times f_{fll\_ref}$   | _                               | 23.99     | _                     | MHz               | 5, 6  |
|                          |  | Mid range (DRS = 01)<br>$1464 \times f_{fll\_ref}$  | _                               | 47.97     | _                     | MHz               |       |
| J <sub>cyc_fll</sub>     | FLL period jitter  |   | _                               | 180       | _                     | ps                | 7     |
| , –                      | • f <sub>VCO</sub> = 48 M  | lHz   |                                 |           |                       |                   |       |
| t <sub>fll_acquire</sub> | FLL target freque  | ncy acquisition time  | _                               | _         | 1                     | ms                | 8     |
|                          |  | Pl  | L                               |           | '                     |                   |       |
| f <sub>vco</sub>         | VCO operating fre  | equency   | 48.0                            | _         | 100                   | MHz               |       |
| I <sub>pil</sub>         |  | rrent<br>IHz (f <sub>osc_hi_1</sub> = 8 MHz, f <sub>pll_ref</sub> =<br>V multiplier = 48)     | _                               | 1060      | _                     | μΑ                | 9     |
| I <sub>pll</sub>         | PLL operating current  • PLL at 48 MHz (f <sub>osc_hi_1</sub> = 8 MHz, f <sub>pll_ref</sub> = 2 MHz, VDIV multiplier = 24) |   | _                               | 600       | _                     | μΑ                | 9     |
| f <sub>pll_ref</sub>     | PLL reference fre  | quency range  | 2.0                             | _         | 4.0                   | MHz               |       |
| J <sub>cyc_pll</sub>     | PLL period jitter (I   | RMS)  |                                 |           |                       |                   | 10    |
|                          | • f <sub>vco</sub> = 48 MH   | <del>l</del> z  | _                               | 120       | _                     | ps                |       |
|                          | • f <sub>vco</sub> = 100 M   | lHz   | _                               | 50        | _                     | ps                |       |

+ 1075(1/ f<sub>pll ref</sub>)



| Symbol                | Description                           | Min.   | Тур. | Max.                   | Unit | Notes |
|-----------------------|---------------------------------------|--------|------|------------------------|------|-------|
| J <sub>acc_pll</sub>  | PLL accumulated jitter over 1µs (RMS) |        |      |                        |      | 10    |
|                       | • f <sub>vco</sub> = 48 MHz           | _      | 1350 | _                      | ps   |       |
|                       | • f <sub>vco</sub> = 100 MHz          | _      | 600  | _                      | ps   |       |
| D <sub>lock</sub>     | Lock entry frequency tolerance        | ± 1.49 | _    | ± 2.98                 | %    |       |
| D <sub>unl</sub>      | Lock exit frequency tolerance         | ± 4.47 | _    | ± 5.97                 | %    |       |
| t <sub>pll_lock</sub> | Lock detector detection time          | _      | _    | 150 × 10 <sup>-6</sup> | s    | 11    |

Table 18. MCG specifications (continued)

- 1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
- 2. The deviation is relative to the factory trimmed frequency at nominal V<sub>DD</sub> and 25 °C, f<sub>ints ft</sub>.
- 3. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 0.
- The resulting system clock frequencies must not exceed their maximum specified values. The DCO frequency deviation (Δf<sub>dco t</sub>) over voltage and temperature must be considered.
- 5. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 1.
- 6. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
- 7. This specification is based on standard deviation (RMS) of period or frequency.
- 8. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
- 9. Excludes any oscillator currents that are also consuming power while PLL is in operation.
- 10. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
- 11. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

#### 3.3.2 Oscillator electrical specifications

## 3.3.2.1 Oscillator DC electrical specifications Table 19. Oscillator DC electrical specifications

| Symbol             | Description                             | Min. | Тур. | Max. | Unit | Notes |
|--------------------|---|------|------|------|------|-------|
| $V_{DD}$           | Supply voltage                          | 1.71 | _    | 3.6  | V    |       |
| I <sub>DDOSC</sub> | Supply current — low-power mode (HGO=0) |      |      |      |      | 1     |
|                    | • 32 kHz                                | _    | 500  | _    | nA   |       |
|                    | • 4 MHz                                 | _    | 200  | _    | μΑ   |       |
|                    | • 8 MHz (RANGE=01)                      | _    | 300  | _    | μΑ   |       |
|                    | • 16 MHz                                | _    | 950  | _    | μΑ   |       |
|                    |   | _    | 1.2  | _    | mA   |       |



Table 19. Oscillator DC electrical specifications (continued)

| Symbol                       | Description  | Min. | Тур.            | Max. | Unit | Notes |
|------------------------------|--|------|-----------------|------|------|-------|
|                              | • 24 MHz   | _    | 1.5             | _    | mA   |       |
|                              | • 32 MHz   |      |                 |      |      |       |
| I <sub>DDOSC</sub>           | Supply current — high gain mode (HGO=1)  |      |                 |      |      | 1     |
|                              | • 32 kHz   | _    | 25              | _    | μΑ   |       |
|                              | • 4 MHz  | _    | 400             | _    | μΑ   |       |
|                              | • 8 MHz (RANGE=01)   | _    | 500             | _    | μA   |       |
|                              | • 16 MHz   | _    | 2.5             | _    | mA   |       |
|                              | • 24 MHz   | _    | 3               | _    | mA   |       |
|                              | • 32 MHz   | _    | 4               | _    | mA   |       |
| C <sub>x</sub>               | EXTAL load capacitance   | _    | _               | _    |      | 2, 3  |
| Су                           | XTAL load capacitance  | _    | _               | _    |      | 2, 3  |
| R <sub>F</sub>               | Feedback resistor — low-frequency, low-power mode (HGO=0)  | _    | _               | _    | ΜΩ   | 2, 4  |
|                              | Feedback resistor — low-frequency, high-gain mode (HGO=1)  | _    | 10              | _    | ΜΩ   |       |
|                              | Feedback resistor — high-frequency, low-power mode (HGO=0)                                       | _    | _               | _    | ΜΩ   |       |
|                              | Feedback resistor — high-frequency, high-gain mode (HGO=1)                                       | _    | 1               | _    | ΜΩ   |       |
| R <sub>S</sub>               | Series resistor — low-frequency, low-power mode (HGO=0)  | _    | _               | _    | kΩ   |       |
|                              | Series resistor — low-frequency, high-gain mode (HGO=1)  | _    | 200             | _    | kΩ   |       |
|                              | Series resistor — high-frequency, low-power mode (HGO=0)   | _    | _               | _    | kΩ   |       |
|                              | Series resistor — high-frequency, high-gain mode (HGO=1)   |      |                 |      |      |       |
|                              |  | _    | 0               | _    | kΩ   |       |
| V <sub>pp</sub> <sup>5</sup> | Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)  | _    | 0.6             | _    | V    |       |
|                              | Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)  | _    | V <sub>DD</sub> | _    | V    |       |
|                              | Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0) | _    | 0.6             | _    | V    |       |
|                              | Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1) | _    | V <sub>DD</sub> | _    | V    |       |

V<sub>DD</sub>=3.3 V, Temperature =25 °C
 See crystal or resonator manufacturer's recommendation



- 3.  $C_x$ ,  $C_y$  can be provided by using the integrated capacitors when the low frequency oscillator (RANGE = 00) is used. For all other cases external capacitors must be used.
- 4. When low power mode is selected, R<sub>F</sub> is integrated and must not be attached externally.
- 5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

## 3.3.2.2 Oscillator frequency specifications Table 20. Oscillator frequency specifications

| Symbol                | Description   | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|---|------|------|------|------|-------|
| f <sub>osc_lo</sub>   | Oscillator crystal or resonator frequency — low-frequency mode (MCG_C2[RANGE]=00)               | 32   | _    | 40   | kHz  |       |
| f <sub>osc_hi_1</sub> | Oscillator crystal or resonator frequency — high-frequency mode (low range) (MCG_C2[RANGE]=01)  | 3    | _    | 8    | MHz  |       |
| f <sub>osc_hi_2</sub> | Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x) | 8    | _    | 32   | MHz  |       |
| f <sub>ec_extal</sub> | Input clock frequency (external clock mode)   | _    | _    | 48   | MHz  | 1, 2  |
| t <sub>dc_extal</sub> | Input clock duty cycle (external clock mode)  | 40   | 50   | 60   | %    |       |
| t <sub>cst</sub>      | Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0)                             | _    | 750  | _    | ms   | 3, 4  |
|                       | Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1)                             | _    | 250  | _    | ms   |       |
|                       | Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0)          | _    | 0.6  | _    | ms   |       |
|                       | Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1)          | _    | 1    | _    | ms   |       |

- 1. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.
- 2. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.
- 3. Proper PC board layout procedures must be followed to achieve specifications.
- 4. Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG\_S register being set.

#### 3.4 Memories and memory interfaces

#### 3.4.1 Flash electrical specifications

This section describes the electrical characteristics of the flash memory module.



#### 3.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

Table 21. NVM program/erase timing specifications

| Symbol                | Description                        | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|------------------------------------|------|------|------|------|-------|
| t <sub>hvpgm4</sub>   | Longword Program high-voltage time | _    | 7.5  | 18   | μs   | _     |
| t <sub>hversscr</sub> | Sector Erase high-voltage time     | _    | 13   | 113  | ms   | 1     |
| t <sub>hversall</sub> | Erase All high-voltage time        | _    | 52   | 452  | ms   | 1     |

<sup>1.</sup> Maximum time based on expectations at cycling end-of-life.

## 3.4.1.2 Flash timing specifications — commands Table 22. Flash command timing specifications

| Symbol                | Description                                   | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|---|------|------|------|------|-------|
| t <sub>rd1sec1k</sub> | Read 1s Section execution time (flash sector) | _    | _    | 60   | μs   | 1     |
| t <sub>pgmchk</sub>   | Program Check execution time                  | _    | _    | 45   | μs   | 1     |
| t <sub>rdrsrc</sub>   | Read Resource execution time                  | _    | _    | 30   | μs   | 1     |
| t <sub>pgm4</sub>     | Program Longword execution time               | _    | 65   | 145  | μs   | _     |
| t <sub>ersscr</sub>   | Erase Flash Sector execution time             | _    | 14   | 114  | ms   | 2     |
| t <sub>rd1all</sub>   | Read 1s All Blocks execution time             | _    | _    | 1.8  | ms   | _     |
| t <sub>rdonce</sub>   | Read Once execution time                      | _    | _    | 25   | μs   | 1     |
| t <sub>pgmonce</sub>  | Program Once execution time                   | _    | 65   | _    | μs   | _     |
| t <sub>ersall</sub>   | Erase All Blocks execution time               | _    | 88   | 650  | ms   | 2     |
| t <sub>vfykey</sub>   | Verify Backdoor Access Key execution time     | _    | _    | 30   | μs   | 1     |

<sup>1.</sup> Assumes 25 MHz flash clock frequency.

## 3.4.1.3 Flash high voltage current behaviors Table 23. Flash high voltage current behaviors

| Symbol              | Description   | Min. | Тур. | Max. | Unit |
|---------------------|---|------|------|------|------|
| I <sub>DD_PGM</sub> | Average current adder during high voltage flash programming operation | _    | 2.5  | 6.0  | mA   |
| I <sub>DD_ERS</sub> | Average current adder during high voltage flash erase operation       | _    | 1.5  | 4.0  | mA   |

<sup>2.</sup> Maximum times for erase parameters based on expectations at cycling end-of-life.



## 3.4.1.4 Reliability specifications Table 24. NVM reliability specifications

| Symbol                  | Description                            | Min.    | Typ. <sup>1</sup> | Max. | Unit   | Notes |
|-------------------------|--|---------|-------------------|------|--------|-------|
|                         | Prograi                                | m Flash |                   |      |        |       |
| t <sub>nvmretp10k</sub> | Data retention after up to 10 K cycles | 5       | 50                | _    | years  | _     |
| t <sub>nvmretp1k</sub>  | Data retention after up to 1 K cycles  | 20      | 100               | _    | years  | _     |
| n <sub>nvmcycp</sub>    | Cycling endurance                      | 10 K    | 50 K              | _    | cycles | 2     |

Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25 °C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.

#### 3.5 Security and integrity modules

There are no specifications necessary for the device's security and integrity modules.

#### 3.6 Analog

#### 3.6.1 ADC electrical specifications

The 16-bit accuracy specifications listed in Table 25 and Table 26 are achievable on the differential pins ADCx\_DP0, ADCx\_DM0.

All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

## 3.6.1.1 16-bit ADC operating conditions Table 25. 16-bit ADC operating conditions

| Symbol            | Description                | Conditions   | Min.             | Typ. <sup>1</sup> | Max.             | Unit | Notes |
|-------------------|----------------------------|--|------------------|-------------------|------------------|------|-------|
| $V_{DDA}$         | Supply voltage             | Absolute   | 1.71             | _                 | 3.6              | V    | _     |
| $\Delta V_{DDA}$  | Supply voltage             | Delta to V <sub>DD</sub> (V <sub>DD</sub> – V <sub>DDA</sub> ) | -100             | 0                 | +100             | mV   | 2     |
| $\Delta V_{SSA}$  | Ground voltage             | Delta to V <sub>SS</sub> (V <sub>SS</sub> – V <sub>SSA</sub> ) | -100             | 0                 | +100             | mV   | 2     |
| V <sub>REFH</sub> | ADC reference voltage high |  | 1.13             | $V_{DDA}$         | $V_{DDA}$        | V    | 3     |
| V <sub>REFL</sub> | ADC reference voltage low  |  | V <sub>SSA</sub> | V <sub>SSA</sub>  | V <sub>SSA</sub> | V    | 3     |

<sup>2.</sup> Cycling endurance represents number of program/erase cycles at -40 °C ≤ T<sub>i</sub> ≤ 125 °C.





Table 25. 16-bit ADC operating conditions (continued)

| Symbol            | Description                    | Conditions   | Min.   | Typ. <sup>1</sup> | Max.             | Unit | Notes |
|-------------------|--------------------------------|--|--------|-------------------|------------------|------|-------|
| V <sub>ADIN</sub> | Input voltage                  | 16-bit differential mode                                   | VREFL  | _                 | 31/32 *<br>VREFH | V    | _     |
|                   |                                | All other modes  | VREFL  | _                 | VREFH            |      |       |
| C <sub>ADIN</sub> | Input                          | 16-bit mode  | _      | 8                 | 10               | pF   | _     |
|                   | capacitance                    | 8-bit / 10-bit / 12-bit<br>modes                           | _      | 4                 | 5                |      |       |
| R <sub>ADIN</sub> | Input series resistance        |  | _      | 2                 | 5                | kΩ   | _     |
| R <sub>AS</sub>   | Analog source                  | 13-bit / 12-bit modes                                      |        |                   |                  |      | 4     |
|                   | resistance<br>(external)       | f <sub>ADCK</sub> < 4 MHz                                  | _      | _                 | 5                | kΩ   |       |
| f <sub>ADCK</sub> | ADC conversion clock frequency | ≤ 13-bit mode  | 1.0    | _                 | 18.0             | MHz  | 5     |
| f <sub>ADCK</sub> | ADC conversion clock frequency | 16-bit mode  | 2.0    | _                 | 12.0             | MHz  | 5     |
| C <sub>rate</sub> | ADC conversion                 | ≤ 13-bit modes   |        |                   |                  |      | 6     |
|                   | rate                           | No ADC hardware averaging                                  | 20.000 | _                 | 818.330          | Ksps |       |
|                   |                                | Continuous conversions enabled, subsequent conversion time |        |                   |                  |      |       |
| C <sub>rate</sub> | ADC conversion                 | 16-bit mode  |        |                   |                  |      | 6     |
|                   | rate                           | No ADC hardware averaging                                  | 37.037 | _                 | 461.467          | Ksps |       |
|                   |                                | Continuous conversions enabled, subsequent conversion time |        |                   |                  |      |       |

<sup>1.</sup> Typical values assume  $V_{DDA}$  = 3.0 V, Temp = 25 °C,  $f_{ADCK}$  = 1.0 MHz, unless otherwise stated. Typical values are for reference only, and are not tested in production.

- 5. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
- 6. For guidelines and examples of conversion rate calculation, download the ADC calculator tool.

<sup>2.</sup> DC potential difference.

<sup>3.</sup> For packages without dedicated VREFH and VREFL pins,  $V_{REFH}$  is internally tied to  $V_{DDA}$ , and  $V_{REFL}$  is internally tied to  $V_{SSA}$ .

<sup>4.</sup> This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had < 8  $\Omega$  analog source resistance. The  $R_{AS}/C_{AS}$  time constant should be kept to < 1 ns.



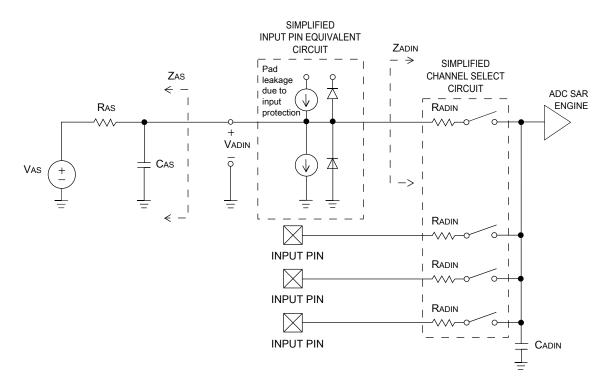


Figure 7. ADC input impedance equivalency diagram

#### 3.6.1.2 16-bit ADC electrical characteristics

Table 26. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )

| Symbol               | Description                    | Conditions <sup>1</sup>     | Min.          | Typ. <sup>2</sup> | Max.            | Unit             | Notes                |
|----------------------|--------------------------------|-----------------------------|---------------|-------------------|-----------------|------------------|----------------------|
| I <sub>DDA_ADC</sub> | Supply current                 |                             | 0.215         | _                 | 1.7             | mA               | 3                    |
|                      | ADC                            | ADLPC = 1, ADHSC =          | 1.2           | 2.4               | 3.9             | MHz              | t <sub>ADACK</sub> = |
|                      | asynchronous<br>clock source   | 0                           | 2.4           | 4.0               | 6.1             | MHz              | 1/f <sub>ADACK</sub> |
|                      | clock source                   | • ADLPC = 1, ADHSC = 1      | 3.0           | 5.2               | 7.3             | MHz              |                      |
| f <sub>ADACK</sub>   |                                | • ADLPC = 0, ADHSC = 0      | 4.4           | 6.2               | 9.5             | MHz              |                      |
|                      |                                | • ADLPC = 0, ADHSC = 1      |               |                   |                 |                  |                      |
|                      | Sample Time                    | See Reference Manual chapte | er for sample | times             | '               |                  | !                    |
| TUE                  | Total unadjusted               | 12-bit modes                | _             | ±4                | ±6.8            | LSB <sup>4</sup> | 5                    |
|                      | error                          | <12-bit modes               | _             | ±1.4              | ±2.1            |                  |                      |
| DNL                  | Differential non-<br>linearity | 12-bit modes                | _             | ±0.7              | -1.1 to<br>+1.9 | LSB <sup>4</sup> | 5                    |
|                      |                                | • <12-bit modes             | _             | ±0.2              | -0.3 to 0.5     |                  |                      |



Table 26. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ ) (continued)

| Symbol              | Description                     | Conditions <sup>1</sup>                         | Min. | Typ. <sup>2</sup>      | Max.            | Unit             | Notes  |
|---------------------|---------------------------------|---|------|------------------------|-----------------|------------------|--|
| INL                 | Integral non-<br>linearity      | 12-bit modes                                    | _    | ±1.0                   | -2.7 to<br>+1.9 | LSB <sup>4</sup> | 5  |
|                     |                                 | <12-bit modes                                   | _    | ±0.5                   | -0.7 to<br>+0.5 |                  |  |
| E <sub>FS</sub>     | Full-scale error                | 12-bit modes                                    | _    | -4                     | -5.4            | LSB <sup>4</sup> | V <sub>ADIN</sub> =  |
|                     |                                 | <ul><li>&lt;12-bit modes</li></ul>              | _    | -1.4                   | -1.8            |                  | V <sub>DDA</sub> <sup>5</sup>  |
| E <sub>Q</sub>      | Quantization                    | 16-bit modes                                    | _    | -1 to 0                | _               | LSB <sup>4</sup> |  |
|                     | error                           | • ≤13-bit modes                                 | _    | _                      | ±0.5            |                  |  |
| ENOB                | Effective number of bits        | 16-bit differential mode                        | 12.8 | 14.5                   | _               | bits             | 6  |
|                     | of bits                         | <ul><li>Avg = 32</li><li>Avg = 4</li></ul>      | 11.9 | 13.8                   | _               | bits             |  |
|                     |                                 |   | 12.2 | 13.9                   | _               | bits             |  |
|                     |                                 | 16-bit single-ended mode  • Avg = 32            | 11.4 | 13.1                   | _               | bits             |  |
|                     |                                 | • Avg = 32                                      |      |                        |                 |                  |  |
| SINAD               | Signal-to-noise plus distortion | See ENOB  | 6.02 | 2 × ENOB +             | 1.76            | dB               |  |
| THD                 | Total harmonic distortion       | 16-bit differential mode                        | _    | -94                    | _               | dB               | 7  |
|                     | distortion                      | • Avg = 32                                      | _    | -85                    | _               | dB               |  |
|                     |                                 | 16-bit single-ended mode                        |      |                        |                 |                  |  |
|                     |                                 | • Avg = 32                                      |      |                        |                 |                  |  |
| SFDR                | Spurious free                   | 16-bit differential mode                        | 82   | 95                     | _               | dB               | 7  |
|                     | dynamic range                   | • Avg = 32                                      | 78   | 90                     |                 | dB               |  |
|                     |                                 | 16-bit single-ended mode                        | 70   | 90                     | _               | ub               |  |
|                     |                                 | • Avg = 32                                      |      |                        |                 |                  |  |
|                     |                                 | 7.Wg = 02                                       |      |                        |                 |                  |  |
| E <sub>IL</sub>     | Input leakage<br>error          |   |      | $I_{ln} \times R_{AS}$ |                 | mV               | I <sub>In</sub> =<br>leakage<br>current                                      |
|                     |                                 |   |      |                        |                 |                  | (refer to<br>the MCU's<br>voltage<br>and<br>current<br>operating<br>ratings) |
|                     | Temp sensor slope               | Across the full temperature range of the device | 1.55 | 1.62                   | 1.69            | mV/°C            | 8  |
| V <sub>TEMP25</sub> | Temp sensor voltage             | 25 °C   | 706  | 716                    | 726             | mV               | 8  |



- 1. All accuracy numbers assume the ADC is calibrated with  $V_{\text{REFH}} = V_{\text{DDA}}$
- 2. Typical values assume V<sub>DDA</sub> = 3.0 V, Temp = 25 °C, f<sub>ADCK</sub> = 2.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
- The ADC supply current depends on the ADC conversion clock speed, conversion rate and ADC\_CFG1[ADLPC] (low power). For lowest power operation, ADC\_CFG1[ADLPC] must be set, the ADC\_CFG2[ADHSC] bit must be clear with 1 MHz ADC conversion clock speed.
- 4.  $1 LSB = (V_{REFH} V_{REFL})/2^{N}$
- 5. ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
- 6. Input data is 100 Hz sine wave. ADC conversion clock < 12 MHz.
- 7. Input data is 1 kHz sine wave. ADC conversion clock < 12 MHz.
- 8. ADC conversion clock < 3 MHz

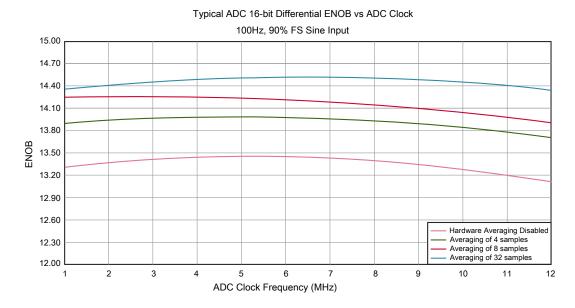


Figure 8. Typical ENOB vs. ADC\_CLK for 16-bit differential mode

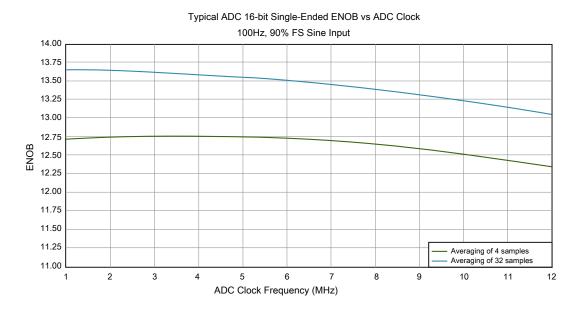


Figure 9. Typical ENOB vs. ADC\_CLK for 16-bit single-ended mode



### 3.6.2 CMP and 6-bit DAC electrical specifications

#### Table 27. Comparator and 6-bit DAC electrical specifications

| Symbol             | Description  | Min.                  | Тур. | Max.     | Unit             |
|--------------------|--|-----------------------|------|----------|------------------|
| $V_{DD}$           | Supply voltage   | 1.71                  | _    | 3.6      | V                |
| I <sub>DDHS</sub>  | Supply current, high-speed mode (EN = 1, PMODE = 1)    | _                     | _    | 200      | μΑ               |
| I <sub>DDLS</sub>  | Supply current, low-speed mode (EN = 1, PMODE = 0)     | _                     | _    | 20       | μΑ               |
| V <sub>AIN</sub>   | Analog input voltage                                   | V <sub>SS</sub>       | _    | $V_{DD}$ | V                |
| V <sub>AIO</sub>   | Analog input offset voltage                            | -                     | _    | 20       | mV               |
| V <sub>H</sub>     | Analog comparator hysteresis <sup>1</sup>              |                       |      |          |                  |
|                    | • CR0[HYSTCTR] = 00                                    | _                     | 5    | _        | mV               |
|                    | • CR0[HYSTCTR] = 01                                    | _                     | 10   | _        | mV               |
|                    | • CR0[HYSTCTR] = 10                                    | _                     | 20   | _        | mV               |
|                    | • CR0[HYSTCTR] = 11                                    | _                     | 30   | _        | mV               |
| V <sub>CMPOh</sub> | Output high  | V <sub>DD</sub> – 0.5 | _    | _        | V                |
| V <sub>CMPOI</sub> | Output low   | _                     | _    | 0.5      | V                |
| t <sub>DHS</sub>   | Propagation delay, high-speed mode (EN = 1, PMODE = 1) | 20                    | 50   | 200      | ns               |
| t <sub>DLS</sub>   | Propagation delay, low-speed mode (EN = 1, PMODE = 0)  | 80                    | 250  | 600      | ns               |
|                    | Analog comparator initialization delay <sup>2</sup>    | -                     | _    | 40       | μs               |
| I <sub>DAC6b</sub> | 6-bit DAC current adder (enabled)                      | _                     | 7    | _        | μΑ               |
| INL                | 6-bit DAC integral non-linearity                       | -0.5                  | _    | 0.5      | LSB <sup>3</sup> |
| DNL                | 6-bit DAC differential non-linearity                   | -0.3                  | _    | 0.3      | LSB              |

<sup>1.</sup> Typical hysteresis is measured with input voltage range limited to 0.7 to  $V_{DD}$  – 0.7 V.

<sup>2.</sup> Comparator initialization delay is defined as the time between software writes to change control inputs (writes to DACEN, VRSEL, PSEL, MSEL, VOSEL) and the comparator output settling to a stable level.

<sup>3.</sup>  $1 LSB = V_{reference}/64$ 



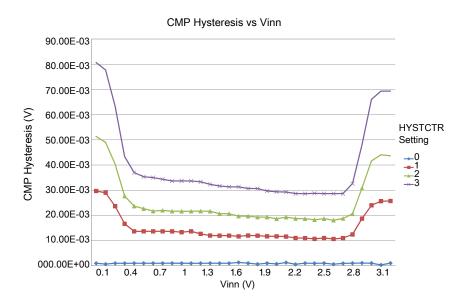


Figure 10. Typical hysteresis vs. Vin level ( $V_{DD} = 3.3 \text{ V}$ , PMODE = 0)

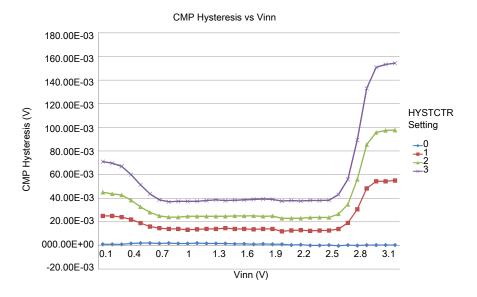


Figure 11. Typical hysteresis vs. Vin level ( $V_{DD} = 3.3 \text{ V}$ , PMODE = 1)

#### 3.6.3 12-bit DAC electrical characteristics



# 3.6.3.1 12-bit DAC operating requirements Table 28. 12-bit DAC operating requirements

| Symbol            | Desciption              | Min. | Max. | Unit | Notes |
|-------------------|-------------------------|------|------|------|-------|
| $V_{DDA}$         | Supply voltage          | 1.71 | 3.6  | V    |       |
| V <sub>DACR</sub> | Reference voltage       | 1.13 | 3.6  | V    | 1     |
| C <sub>L</sub>    | Output load capacitance | _    | 100  | pF   | 2     |
| ΙL                | Output load current     | _    | 1    | mA   |       |

- 1. The DAC reference can be selected to be  $V_{\text{DDA}}$  or  $V_{\text{REFH}}$ .
- 2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC.

# 3.6.3.2 12-bit DAC operating behaviors Table 29. 12-bit DAC operating behaviors

| Symbol                     | Description  | Min.                      | Тур.     | Max.              | Unit   | Notes |
|----------------------------|--|---------------------------|----------|-------------------|--------|-------|
| I <sub>DDA_DACL</sub><br>P | Supply current — low-power mode  | _                         | _        | 250               | μΑ     |       |
| I <sub>DDA_DACH</sub><br>P | Supply current — high-speed mode   | _                         | _        | 900               | μΑ     |       |
| t <sub>DACLP</sub>         | Full-scale settling time (0x080 to 0xF7F) — low-power mode                       |                           | 100      | 200               | μs     | 1     |
| t <sub>DACHP</sub>         | Full-scale settling time (0x080 to 0xF7F) — high-power mode                      | _                         | 15       | 30                | μs     | 1     |
| t <sub>CCDACLP</sub>       | Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode | _                         | 0.7      | 1                 | μs     | 1     |
| V <sub>dacoutl</sub>       | DAC output voltage range low — high-<br>speed mode, no load, DAC set to 0x000    |                           | _        | 100               | mV     |       |
| V <sub>dacouth</sub>       | DAC output voltage range high — high-<br>speed mode, no load, DAC set to 0xFFF   | V <sub>DACR</sub><br>-100 | _        | V <sub>DACR</sub> | mV     |       |
| INL                        | Integral non-linearity error — high speed mode                                   | _                         | _        | ±8                | LSB    | 2     |
| DNL                        | Differential non-linearity error — V <sub>DACR</sub> > 2<br>V                    | _                         | _        | ±1                | LSB    | 3     |
| DNL                        | Differential non-linearity error — V <sub>DACR</sub> = VREF_OUT                  | _                         | _        | ±1                | LSB    | 4     |
| V <sub>OFFSET</sub>        | Offset error   | _                         | ±0.4     | ±0.8              | %FSR   | 5     |
| E <sub>G</sub>             | Gain error   | _                         | ±0.1     | ±0.6              | %FSR   | 5     |
| PSRR                       | Power supply rejection ratio, V <sub>DDA</sub> ≥ 2.4 V                           | 60                        | _        | 90                | dB     |       |
| T <sub>CO</sub>            | Temperature coefficient offset voltage   | _                         | 3.7      | _                 | μV/C   | 6     |
| T <sub>GE</sub>            | Temperature coefficient gain error   | _                         | 0.000421 | _                 | %FSR/C |       |
| Rop                        | Output resistance (load = $3 \text{ k}\Omega$ )                                  | _                         | _        | 250               | Ω      |       |
| SR                         | Slew rate -80h→ F7Fh→ 80h  |                           |          |                   | V/µs   |       |
|                            |  | 1.2                       | 1.7      | _                 |        |       |



| Table 29. 1 | 2-bit DAC or | perating bel | haviors ( | continued) |
|-------------|--------------|--------------|-----------|------------|
|-------------|--------------|--------------|-----------|------------|

| Symbol | Description                                      | Min. | Тур. | Max. | Unit | Notes |
|--------|--|------|------|------|------|-------|
|        | High power (SP <sub>HP</sub> )                   | 0.05 | 0.12 | _    |      |       |
|        | • Low power (SP <sub>LP</sub> )                  |      |      |      |      |       |
| BW     | 3dB bandwidth                                    |      |      |      | kHz  |       |
|        | <ul> <li>High power (SP<sub>HP</sub>)</li> </ul> | 550  | _    | _    |      |       |
|        | • Low power (SP <sub>LP</sub> )                  | 40   | _    | _    |      |       |

- 1. Settling within ±1 LSB
- 2. The INL is measured for 0 + 100 mV to  $V_{DACR}$  –100 mV
- 3. The DNL is measured for 0 + 100 mV to  $V_{DACR}$  –100 mV
- 4. The DNL is measured for 0 + 100 mV to  $V_{DACR}$  -100 mV with  $V_{DDA}$  > 2.4 V 5. Calculated by a best fit curve from  $V_{SS}$  + 100 mV to  $V_{DACR}$  100 mV
- 6.  $V_{DDA} = 3.0 \text{ V}$ , reference select set for  $V_{DDA}$  (DACx\_CO:DACRFS = 1), high power mode (DACx\_CO:LPEN = 0), DAC set to 0x800, temperature range is across the full range of the device

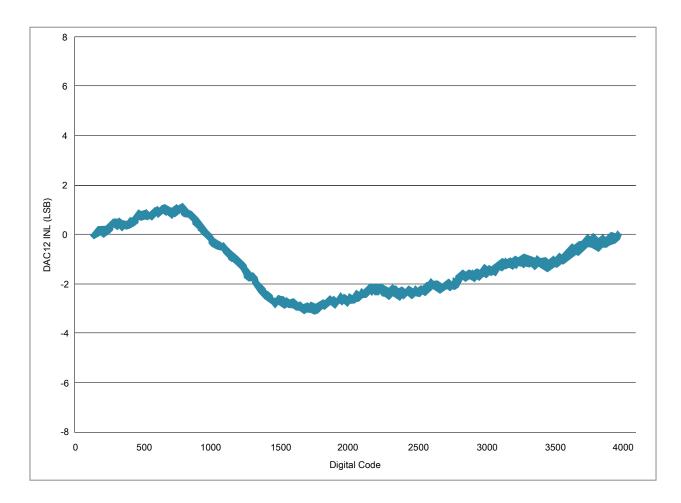


Figure 12. Typical INL error vs. digital code



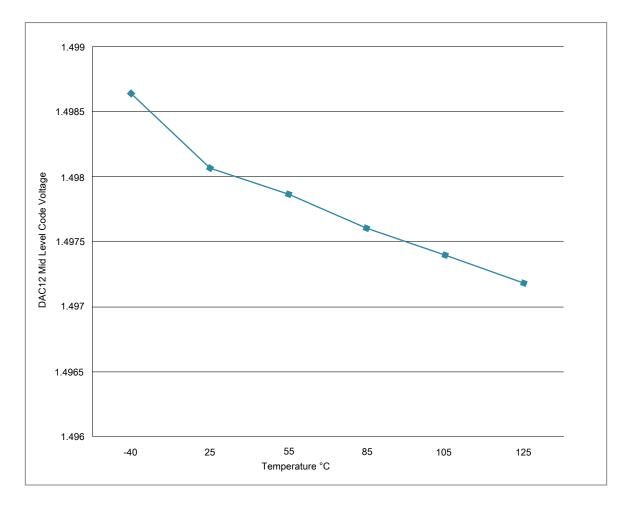


Figure 13. Offset at half scale vs. temperature

#### 3.7 Timers

See General switching specifications.

#### 3.8 Communication interfaces

### 3.8.1 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit **usb.org**.



#### **NOTE**

The MCGPLLCLK meets the USB jitter specifications for certification with the use of an external clock/crystal for both Device and Host modes.

The MCGFLLCLK does not meet the USB jitter specifications for certification.

# 3.8.2 USB VREG electrical specifications Table 30. USB VREG electrical specifications

| Symbol                | Description   | Min.   | Typ. <sup>1</sup> | Max. | Unit     | Notes |
|-----------------------|---|--------|-------------------|------|----------|-------|
| VREGIN                | Input supply voltage  | 2.7    | _                 | 5.5  | V        |       |
| I <sub>DDon</sub>     | Quiescent current — Run mode, load current equal zero, input supply (VREGIN) > 3.6 V                                  | _      | 125               | 186  | μА       |       |
| I <sub>DDstby</sub>   | Quiescent current — Standby mode, load current equal zero   | _      | 1.1               | 10   | μΑ       |       |
| I <sub>DDoff</sub>    | Quiescent current — Shutdown mode  • VREGIN = 5.0 V and temperature=25 °C  • Across operating voltage and temperature | _<br>_ | 650<br>—          | 4    | nA<br>μA |       |
| I <sub>LOADrun</sub>  | Maximum load current — Run mode   | _      | _                 | 120  | mA       |       |
| I <sub>LOADstby</sub> | Maximum load current — Standby mode   | _      | _                 | 1    | mA       |       |
| V <sub>Reg33out</sub> | Regulator output voltage — Input supply (VREGIN) > 3.6 V  |        |                   |      |          |       |
|                       | Run mode     Standby mode   | 3      | 3.3               | 3.6  | V        |       |
|                       | Standay mode  | 2.1    | 2.8               | 3.6  | V        |       |
| V <sub>Reg33out</sub> | Regulator output voltage — Input supply (VREGIN) < 3.6 V, pass-through mode   | 2.1    |                   | 3.6  | V        | 2     |
| C <sub>OUT</sub>      | External output capacitor   | 1.76   | 2.2               | 8.16 | μF       |       |
| ESR                   | External output capacitor equivalent series resistance  | 1      | _                 | 100  | mΩ       |       |
| I <sub>LIM</sub>      | Short circuit current   | _      | 290               | _    | mA       |       |

- 1. Typical values assume VREGIN = 5.0 V, Temp =  $25 \,^{\circ}\text{C}$  unless otherwise stated.
- 2. Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I<sub>Load</sub>.



#### 3.8.3 SPI switching specifications

The Serial Peripheral Interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. See the SPI chapter of the chip's Reference Manual for information about the modified transfer formats used for communicating with slower peripheral devices.

All timing is shown with respect to  $20\%~V_{DD}$  and  $80\%~V_{DD}$  thresholds, unless noted, as well as input signal transitions of 3 ns and a 30 pF maximum load on all SPI pins.

| Num. | Symbol             | Description                    | Min.                      | Max.                          | Unit               | Note |
|------|--------------------|--------------------------------|---------------------------|-------------------------------|--------------------|------|
| 1    | f <sub>op</sub>    | Frequency of operation         | f <sub>periph</sub> /2048 | f <sub>periph</sub> /2        | Hz                 | 1    |
| 2    | t <sub>SPSCK</sub> | SPSCK period                   | 2 x t <sub>periph</sub>   | 2048 x<br>t <sub>periph</sub> | ns                 | 2    |
| 3    | t <sub>Lead</sub>  | Enable lead time               |                           | _                             | t <sub>SPSCK</sub> | _    |
| 4    | t <sub>Lag</sub>   | Enable lag time                | 1/2                       | 1/2 —                         |                    | _    |
| 5    | twspsck            | Clock (SPSCK) high or low time | t <sub>periph</sub> – 30  | 1024 x<br>t <sub>periph</sub> | ns                 | _    |
| 6    | t <sub>SU</sub>    | Data setup time (inputs)       | 16                        | _                             | ns                 | _    |
| 7    | t <sub>HI</sub>    | Data hold time (inputs)        | 0                         | _                             | ns                 | _    |
| 8    | t <sub>v</sub>     | Data valid (after SPSCK edge)  | _                         | 10                            | ns                 | _    |
| 9    | t <sub>HO</sub>    | Data hold time (outputs)       | 0                         | _                             | ns                 | _    |
| 10   | t <sub>RI</sub>    | Rise time input                | _                         | t <sub>periph</sub> – 25      | ns                 | _    |
|      | t <sub>FI</sub>    | Fall time input                |                           |                               |                    |      |
| 11   | t <sub>RO</sub>    | Rise time output               | _                         | 25                            | ns                 | _    |

Table 31. SPI master mode timing on slew rate disabled pads

Fall time output

 $t_{FO}$ 

Table 32. SPI master mode timing on slew rate enabled pads

| Num. | Symbol              | Description                    | Min.                      | Max.                          | Unit               | Note |
|------|---------------------|--------------------------------|---------------------------|-------------------------------|--------------------|------|
| 1    | f <sub>op</sub>     | Frequency of operation         | f <sub>periph</sub> /2048 | f <sub>periph</sub> /2        | Hz                 | 1    |
| 2    | t <sub>SPSCK</sub>  | SPSCK period                   | 2 x t <sub>periph</sub>   | 2048 x<br>t <sub>periph</sub> | ns                 | 2    |
| 3    | t <sub>Lead</sub>   | Enable lead time               | 1/2                       | _                             | t <sub>SPSCK</sub> | _    |
| 4    | t <sub>Lag</sub>    | Enable lag time                | 1/2                       | _                             | t <sub>SPSCK</sub> | _    |
| 5    | t <sub>WSPSCK</sub> | Clock (SPSCK) high or low time | t <sub>periph</sub> – 30  | 1024 x<br>t <sub>periph</sub> | ns                 | _    |
| 6    | t <sub>SU</sub>     | Data setup time (inputs)       | 96                        | _                             | ns                 | _    |

Table continues on the next page...

<sup>1.</sup> For SPI0,  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).

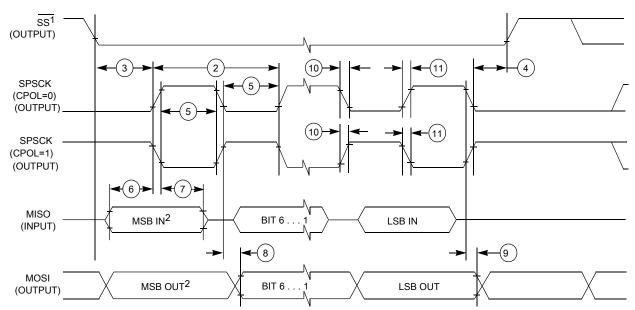
<sup>2.</sup>  $t_{periph} = 1/f_{periph}$ 



| Table 32. | SPI master mode timing | on slew rate enabled | pads (continued) |
|-----------|------------------------|----------------------|------------------|
|-----------|------------------------|----------------------|------------------|

| Num. | Symbol          | Description                   | Min. | Max.                     | Unit | Note |
|------|-----------------|-------------------------------|------|--------------------------|------|------|
| 7    | t <sub>HI</sub> | Data hold time (inputs)       | 0    | _                        | ns   | _    |
| 8    | t <sub>v</sub>  | Data valid (after SPSCK edge) | _    | 52                       | ns   | _    |
| 9    | t <sub>HO</sub> | Data hold time (outputs)      | 0    | _                        | ns   | _    |
| 10   | t <sub>RI</sub> | Rise time input               | _    | t <sub>periph</sub> – 25 | ns   | _    |
|      | t <sub>FI</sub> | Fall time input               |      |                          |      |      |
| 11   | t <sub>RO</sub> | Rise time output              | _    | 36                       | ns   | _    |
|      | t <sub>FO</sub> | Fall time output              |      |                          |      |      |

- 1. For SPI0,  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).
- 2.  $t_{periph} = 1/f_{periph}$

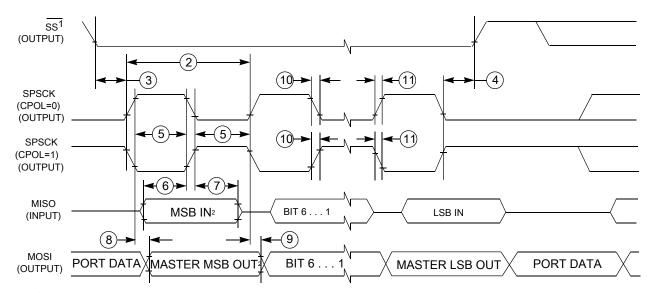


- 1. If configured as an output.
- 2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 14. SPI master mode timing (CPHA = 0)



#### Peripheral operating requirements and behaviors



<sup>1.</sup>If configured as output

Figure 15. SPI master mode timing (CPHA = 1)

Table 33. SPI slave mode timing on slew rate disabled pads

| Num. | Symbol              | Description                    | Min.                     | Max.                     | Unit                | Note |
|------|---------------------|--------------------------------|--------------------------|--------------------------|---------------------|------|
| 1    | f <sub>op</sub>     | Frequency of operation         | 0                        | f <sub>periph</sub> /4   | Hz                  | 1    |
| 2    | t <sub>SPSCK</sub>  | SPSCK period                   | 4 x t <sub>periph</sub>  | x t <sub>periph</sub>    |                     | 2    |
| 3    | t <sub>Lead</sub>   | Enable lead time               | 1                        | _                        | t <sub>periph</sub> | _    |
| 4    | t <sub>Lag</sub>    | Enable lag time                | 1                        | 1 —                      |                     | _    |
| 5    | t <sub>WSPSCK</sub> | Clock (SPSCK) high or low time | t <sub>periph</sub> – 30 | _                        | ns                  | _    |
| 6    | t <sub>SU</sub>     | Data setup time (inputs)       | 2                        | _                        | ns                  | _    |
| 7    | t <sub>HI</sub>     | Data hold time (inputs)        | 7                        | _                        | ns                  | _    |
| 8    | t <sub>a</sub>      | Slave access time              | _                        | t <sub>periph</sub>      | ns                  | 3    |
| 9    | t <sub>dis</sub>    | Slave MISO disable time        | _                        | t <sub>periph</sub>      | ns                  | 4    |
| 10   | t <sub>v</sub>      | Data valid (after SPSCK edge)  | _                        | 22                       | ns                  | _    |
| 11   | t <sub>HO</sub>     | Data hold time (outputs)       | 0                        | _                        | ns                  | _    |
| 12   | t <sub>RI</sub>     | Rise time input                | _                        | t <sub>periph</sub> – 25 | ns                  | _    |
|      | t <sub>Fl</sub>     | Fall time input                |                          |                          |                     |      |
| 13   | t <sub>RO</sub>     | Rise time output               | _                        | 25                       | ns                  | _    |
|      | t <sub>FO</sub>     | Fall time output               |                          |                          |                     |      |

<sup>1.</sup> For SPI0,  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).

<sup>2.</sup> LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

<sup>2.</sup>  $t_{periph} = 1/f_{periph}$ 

<sup>3.</sup> Time to data active from high-impedance state

<sup>4.</sup> Hold time to high-impedance state



| Num. | Symbol              | Description                    | Min.                                | Max.                     | Unit                | Note |
|------|---------------------|--------------------------------|-------------------------------------|--------------------------|---------------------|------|
| 1    | f <sub>op</sub>     | Frequency of operation         | 0                                   | f <sub>periph</sub> /4   | Hz                  | 1    |
| 2    | t <sub>SPSCK</sub>  | SPSCK period                   | 4 x t <sub>periph</sub>             | _                        | ns                  | 2    |
| 3    | t <sub>Lead</sub>   | Enable lead time               | 1                                   | _                        | t <sub>periph</sub> | _    |
| 4    | t <sub>Lag</sub>    | Enable lag time                | 1                                   | _                        | t <sub>periph</sub> | _    |
| 5    | t <sub>WSPSCK</sub> | Clock (SPSCK) high or low time | low time t <sub>periph</sub> - 30 — |                          | ns                  | _    |
| 6    | t <sub>SU</sub>     | Data setup time (inputs)       | 2                                   | _                        | ns                  | _    |
| 7    | t <sub>HI</sub>     | Data hold time (inputs)        | 7                                   | _                        | ns                  | _    |
| 8    | ta                  | Slave access time              | _                                   | t <sub>periph</sub>      | ns                  | 3    |
| 9    | t <sub>dis</sub>    | Slave MISO disable time        | _                                   | t <sub>periph</sub>      | ns                  | 4    |
| 10   | t <sub>v</sub>      | Data valid (after SPSCK edge)  | _                                   | 122                      | ns                  | _    |
| 11   | t <sub>HO</sub>     | Data hold time (outputs)       | 0                                   | _                        | ns                  | _    |
| 12   | t <sub>RI</sub>     | Rise time input                |                                     | t <sub>periph</sub> – 25 | ns                  | _    |
|      | t <sub>FI</sub>     | Fall time input                |                                     |                          |                     |      |
| 13   | t <sub>RO</sub>     | Rise time output               | _                                   | 36                       | ns                  | _    |
|      |                     |                                |                                     | I                        | l                   | 1    |

Table 34. SPI slave mode timing on slew rate enabled pads

1. For SPI0,  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).

Fall time output

- 2.  $t_{periph} = 1/f_{periph}$
- 3. Time to data active from high-impedance state
- 4. Hold time to high-impedance state

 $t_{FO}$ 

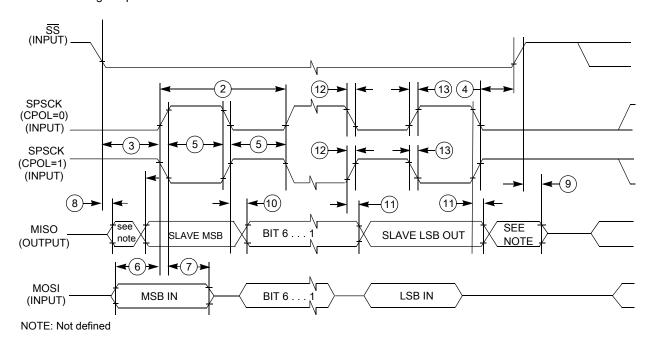


Figure 16. SPI slave mode timing (CPHA = 0)



#### Peripheral operating requirements and behaviors

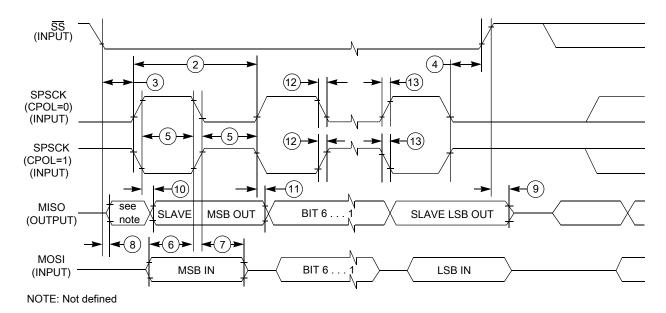


Figure 17. SPI slave mode timing (CPHA = 1)

# 3.8.4 Inter-Integrated Circuit Interface (I2C) timing Table 35. I2C timing

| Characteristic   | Symbol                | Standa           | rd Mode           | Fast                               | Mode             | Unit |
|--|-----------------------|------------------|-------------------|------------------------------------|------------------|------|
|  |                       | Minimum          | Maximum           | Minimum                            | Maximum          |      |
| SCL Clock Frequency  | f <sub>SCL</sub>      | 0                | 100               | 0                                  | 400 <sup>1</sup> | kHz  |
| Hold time (repeated) START condition. After this period, the first clock pulse is generated. | t <sub>HD</sub> ; STA | 4                | _                 | 0.6                                | _                | μs   |
| LOW period of the SCL clock  | t <sub>LOW</sub>      | 4.7              | _                 | 1.3                                | _                | μs   |
| HIGH period of the SCL clock   | t <sub>HIGH</sub>     | 4                | _                 | 0.6                                | _                | μs   |
| Set-up time for a repeated START condition   | t <sub>SU</sub> ; STA | 4.7              | _                 | 0.6                                | _                | μs   |
| Data hold time for I <sup>2</sup> C bus devices  | t <sub>HD</sub> ; DAT | 0 <sup>2</sup>   | 3.45 <sup>3</sup> | 04                                 | 0.9 <sup>2</sup> | μs   |
| Data set-up time   | t <sub>SU</sub> ; DAT | 250 <sup>5</sup> | _                 | 100 <sup>3</sup> , <sup>6</sup>    | _                | ns   |
| Rise time of SDA and SCL signals   | t <sub>r</sub>        | _                | 1000              | 20 +0.1C <sub>b</sub> <sup>7</sup> | 300              | ns   |
| Fall time of SDA and SCL signals   | t <sub>f</sub>        | _                | 300               | 20 +0.1C <sub>b</sub> <sup>6</sup> | 300              | ns   |
| Set-up time for STOP condition   | t <sub>SU</sub> ; STO | 4                | _                 | 0.6                                | _                | μs   |
| Bus free time between STOP and START condition   | t <sub>BUF</sub>      | 4.7              | _                 | 1.3                                | _                | μs   |
| Pulse width of spikes that must be suppressed by the input filter                            | t <sub>SP</sub>       | N/A              | N/A               | 0                                  | 50               | ns   |

<sup>1.</sup> The maximum SCL Clock Frequency in Fast mode with maximum bus loading can only achieved when using the High drive pins (see Voltage and current operating behaviors) or when using the Normal drive pins and VDD ≥ 2.7 V



- The master mode I<sup>2</sup>C deasserts ACK of an address byte simultaneously with the falling edge of SCL. If no slaves
  acknowledge this address byte, then a negative hold time can result, depending on the edge rates of the SDA and
  SCL lines.
- 3. The maximum tHD; DAT must be met only if the device does not stretch the LOW period (tLOW) of the SCL signal.
- 4. Input signal Slew = 10 ns and Output Load = 50 pF
- 5. Set-up time in slave-transmitter mode is 1 IPBus clock period, if the TX FIFO is empty.
- 6. A Fast mode  $I^2C$  bus device can be used in a Standard mode  $I^2C$  bus system, but the requirement  $t_{SU; DAT} \ge 250$  ns must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, then it must output the next data bit to the SDA line  $t_{rmax} + t_{SU; DAT} = 1000 + 250 = 1250$  ns (according to the Standard mode  $I^2C$  bus specification) before the SCL line is released.
- 7. C<sub>b</sub> = total capacitance of the one bus line in pF.

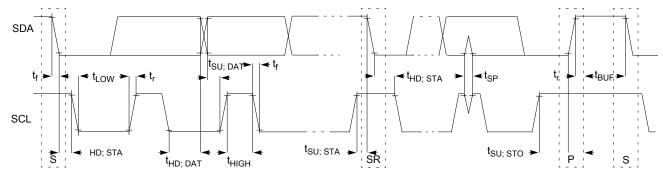


Figure 18. Timing definition for fast and standard mode devices on the I<sup>2</sup>C bus

#### 3.8.5 **UART**

See General switching specifications.

## 3.9 Human-machine interfaces (HMI)

## 3.9.1 TSI electrical specifications

Table 36. TSI electrical specifications

| Symbol    | Description  | Min. | Тур. | Max. | Unit |
|-----------|--|------|------|------|------|
| TSI_RUNF  | Fixed power consumption in run mode  | _    | 100  | _    | μA   |
| TSI_RUNV  | Variable power consumption in run mode (depends on oscillator's current selection) | 1.0  | _    | 128  | μA   |
| TSI_EN    | Power consumption in enable mode   | _    | 100  | _    | μA   |
| TSI_DIS   | Power consumption in disable mode  | _    | 1.2  | _    | μA   |
| TSI_TEN   | TSI analog enable time   | _    | 66   | _    | μs   |
| TSI_CREF  | TSI reference capacitor  | _    | 1.0  | _    | pF   |
| TSI_DVOLT | Voltage variation of VP & VM around nominal values                                 | 0.19 | _    | 1.03 | V    |



#### 4 Dimensions

#### 4.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to **freescale.com** and perform a keyword search for the drawing's document number:

| If you want the drawing for this package | Then use this document number |  |  |  |  |  |
|--|-------------------------------|--|--|--|--|--|
| 32-pin QFN                               | 98ASA00473D                   |  |  |  |  |  |
| 48-pin QFN                               | 98ASA00466D                   |  |  |  |  |  |
| 64-pin LQFP                              | 98ASS23234W                   |  |  |  |  |  |
| 80-pin LQFP                              | 98ASS23174W                   |  |  |  |  |  |

#### 5 Pinout

# 5.1 KL25 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

| 80<br>LQFP | 64<br>LQFP | 48<br>QFN | 32<br>QFN | Pin Name | Default  | ALT0    | ALT1 | ALT2      | ALT3     | ALT4           | ALT5      | ALT6     | ALT7 |
|------------|------------|-----------|-----------|----------|----------|---------|------|-----------|----------|----------------|-----------|----------|------|
| 1          | 1          | -         | 1         | PTE0     | DISABLED |         | PTE0 |           | UART1_TX | RTC_<br>CLKOUT | CMP0_OUT  | I2C1_SDA |      |
| 2          | 2          | _         | _         | PTE1     | DISABLED |         | PTE1 | SPI1_MOSI | UART1_RX |                | SPI1_MISO | I2C1_SCL |      |
| 3          | _          | -         | _         | PTE2     | DISABLED |         | PTE2 | SPI1_SCK  |          |                |           |          |      |
| 4          | _          | _         | _         | PTE3     | DISABLED |         | PTE3 | SPI1_MISO |          |                | SPI1_MOSI |          |      |
| 5          | _          | _         | _         | PTE4     | DISABLED |         | PTE4 | SPI1_PCS0 |          |                |           |          |      |
| 6          | _          | -         | _         | PTE5     | DISABLED |         | PTE5 |           |          |                |           |          |      |
| 7          | 3          | 1         | -         | VDD      | VDD      | VDD     |      |           |          |                |           |          |      |
| 8          | 4          | 2         | 2         | VSS      | VSS      | VSS     |      |           |          |                |           |          |      |
| 9          | 5          | 3         | 3         | USB0_DP  | USB0_DP  | USB0_DP |      |           |          |                |           |          |      |
| 10         | 6          | 4         | 4         | USB0_DM  | USB0_DM  | USB0_DM |      |           |          |                |           |          |      |



| 80<br>LQFP | 64<br>LQFP | 48<br>QFN | 32<br>QFN | Pin Name         | Default                             | ALT0                                | ALT1             | ALT2      | ALT3     | ALT4           | ALT5      | ALT6            | ALT7    |
|------------|------------|-----------|-----------|------------------|-------------------------------------|-------------------------------------|------------------|-----------|----------|----------------|-----------|-----------------|---------|
| 11         | 7          | 5         | 5         | VOUT33           | VOUT33                              | VOUT33                              |                  |           |          |                |           |                 |         |
| 12         | 8          | 6         | 6         | VREGIN           | VREGIN                              | VREGIN                              |                  |           |          |                |           |                 |         |
| 13         | 9          | 7         | -         | PTE20            | ADC0_DP0/<br>ADC0_SE0               | ADC0_DP0/<br>ADC0_SE0               | PTE20            |           | TPM1_CH0 | UARTO_TX       |           |                 |         |
| 14         | 10         | 8         | -         | PTE21            | ADC0_DM0/<br>ADC0_SE4a              | ADC0_DM0/<br>ADC0_SE4a              | PTE21            |           | TPM1_CH1 | UARTO_RX       |           |                 |         |
| 15         | 11         | ı         | -         | PTE22            | ADC0_DP3/<br>ADC0_SE3               | ADC0_DP3/<br>ADC0_SE3               | PTE22            |           | TPM2_CH0 | UART2_TX       |           |                 |         |
| 16         | 12         | ı         | -         | PTE23            | ADC0_DM3/<br>ADC0_SE7a              | ADC0_DM3/<br>ADC0_SE7a              | PTE23            |           | TPM2_CH1 | UART2_RX       |           |                 |         |
| 17         | 13         | 9         | 7         | VDDA             | VDDA                                | VDDA                                |                  |           |          |                |           |                 |         |
| 18         | 14         | 10        | _         | VREFH            | VREFH                               | VREFH                               |                  |           |          |                |           |                 |         |
| 19         | 15         | 11        | _         | VREFL            | VREFL                               | VREFL                               |                  |           |          |                |           |                 |         |
| 20         | 16         | 12        | 8         | VSSA             | VSSA                                | VSSA                                |                  |           |          |                |           |                 |         |
| 21         | 17         | 13        | -         | PTE29            | CMP0_IN5/<br>ADC0_SE4b              | CMP0_IN5/<br>ADC0_SE4b              | PTE29            |           | TPM0_CH2 | TPM_<br>CLKIN0 |           |                 |         |
| 22         | 18         | 14        | 9         | PTE30            | DAC0_OUT/<br>ADC0_SE23/<br>CMP0_IN4 | DAC0_OUT/<br>ADC0_SE23/<br>CMP0_IN4 | PTE30            |           | TPM0_CH3 | TPM_<br>CLKIN1 |           |                 |         |
| 23         | 19         | _         | -         | PTE31            | DISABLED                            |                                     | PTE31            |           | TPM0_CH4 |                |           |                 |         |
| 24         | 20         | 15        | -         | PTE24            | DISABLED                            |                                     | PTE24            |           | TPM0_CH0 |                | I2C0_SCL  |                 |         |
| 25         | 21         | 16        | _         | PTE25            | DISABLED                            |                                     | PTE25            |           | TPM0_CH1 |                | I2C0_SDA  |                 |         |
| 26         | 22         | 17        | 10        | PTA0             | SWD_CLK                             | TSI0_CH1                            | PTA0             |           | TPM0_CH5 |                |           |                 | SWD_CLK |
| 27         | 23         | 18        | 11        | PTA1             | DISABLED                            | TSI0_CH2                            | PTA1             | UARTO_RX  | TPM2_CH0 |                |           |                 |         |
| 28         | 24         | 19        | 12        | PTA2             | DISABLED                            | TSI0_CH3                            | PTA2             | UARTO_TX  | TPM2_CH1 |                |           |                 |         |
| 29         | 25         | 20        | 13        | PTA3             | SWD_DIO                             | TSI0_CH4                            | PTA3             | I2C1_SCL  | TPM0_CH0 |                |           |                 | SWD_DIO |
| 30         | 26         | 21        | 14        | PTA4             | NMI_b                               | TSI0_CH5                            | PTA4             | I2C1_SDA  | TPM0_CH1 |                |           |                 | NMI_b   |
| 31         | 27         | ı         | -         | PTA5             | DISABLED                            |                                     | PTA5             | USB_CLKIN | TPM0_CH2 |                |           |                 |         |
| 32         | 28         | ı         | _         | PTA12            | DISABLED                            |                                     | PTA12            |           | TPM1_CH0 |                |           |                 |         |
| 33         | 29         | ı         | -         | PTA13            | DISABLED                            |                                     | PTA13            |           | TPM1_CH1 |                |           |                 |         |
| 34         | _          | ı         | -         | PTA14            | DISABLED                            |                                     | PTA14            | SPI0_PCS0 | UARTO_TX |                |           |                 |         |
| 35         | _          | -         | _         | PTA15            | DISABLED                            |                                     | PTA15            | SPI0_SCK  | UARTO_RX |                |           |                 |         |
| 36         | _          | _         | _         | PTA16            | DISABLED                            |                                     | PTA16            | SPI0_MOSI |          |                | SPI0_MISO |                 |         |
| 37         | _          | _         | _         | PTA17            | DISABLED                            |                                     | PTA17            | SPI0_MISO |          |                | SPI0_MOSI |                 |         |
| 38         | 30         | 22        | 15        | VDD              | VDD                                 | VDD                                 |                  |           |          |                |           |                 |         |
| 39         | 31         | 23        | 16        | VSS              | VSS                                 | VSS                                 |                  |           |          |                |           |                 |         |
| 40         | 32         | 24        | 17        | PTA18            | EXTAL0                              | EXTAL0                              | PTA18            |           | UART1_RX | TPM_<br>CLKIN0 |           |                 |         |
| 41         | 33         | 25        | 18        | PTA19            | XTAL0                               | XTAL0                               | PTA19            |           | UART1_TX | TPM_<br>CLKIN1 |           | LPTMR0_<br>ALT1 |         |
| 42         | 34         | 26        | 19        | PTA20            | RESET_b                             |                                     | PTA20            |           |          |                |           |                 | RESET_b |
| 43         | 35         | 27        | 20        | PTB0/<br>LLWU_P5 | ADC0_SE8/<br>TSI0_CH0               | ADC0_SE8/<br>TSI0_CH0               | PTB0/<br>LLWU_P5 | I2C0_SCL  | TPM1_CH0 |                |           |                 |         |



#### **Pinout**

| 80   | 64   | 48  | 32  | Pin Name                       | Default                 | ALT0                    | ALT1                           | ALT2      | ALT3            | ALT4           | ALT5      | ALT6     | ALT7 |
|------|------|-----|-----|--------------------------------|-------------------------|-------------------------|--------------------------------|-----------|-----------------|----------------|-----------|----------|------|
| LQFP | LQFP | QFN | QFN | DTD.                           | 1000 050/               | 1000 050/               | DTD.                           | 1000 004  | TDIAL OLIV      |                |           |          |      |
| 44   | 36   | 28  | 21  | PTB1                           | ADC0_SE9/<br>TSI0_CH6   | ADC0_SE9/<br>TSI0_CH6   | PTB1                           | I2C0_SDA  | TPM1_CH1        |                |           |          |      |
| 45   | 37   | 29  | _   | PTB2                           | ADC0_SE12/<br>TSI0_CH7  | ADC0_SE12/<br>TSI0_CH7  | PTB2                           | I2C0_SCL  | TPM2_CH0        |                |           |          |      |
| 46   | 38   | 30  | _   | PTB3                           | ADC0_SE13/<br>TSI0_CH8  | ADC0_SE13/<br>TSI0_CH8  | PTB3                           | I2C0_SDA  | TPM2_CH1        |                |           |          |      |
| 47   | _    | -   | _   | PTB8                           | DISABLED                |                         | PTB8                           |           | EXTRG_IN        |                |           |          |      |
| 48   | _    | _   | _   | PTB9                           | DISABLED                |                         | PTB9                           |           |                 |                |           |          |      |
| 49   | _    | _   | _   | PTB10                          | DISABLED                |                         | PTB10                          | SPI1_PCS0 |                 |                |           |          |      |
| 50   | _    | _   | _   | PTB11                          | DISABLED                |                         | PTB11                          | SPI1_SCK  |                 |                |           |          |      |
| 51   | 39   | 31  | -   | PTB16                          | TSI0_CH9                | TSI0_CH9                | PTB16                          | SPI1_MOSI | UARTO_RX        | TPM_<br>CLKIN0 | SPI1_MISO |          |      |
| 52   | 40   | 32  | -   | PTB17                          | TSI0_CH10               | TSI0_CH10               | PTB17                          | SPI1_MISO | UARTO_TX        | TPM_<br>CLKIN1 | SPI1_MOSI |          |      |
| 53   | 41   | _   | _   | PTB18                          | TSI0_CH11               | TSI0_CH11               | PTB18                          |           | TPM2_CH0        |                |           |          |      |
| 54   | 42   | _   | _   | PTB19                          | TSI0_CH12               | TSI0_CH12               | PTB19                          |           | TPM2_CH1        |                |           |          |      |
| 55   | 43   | 33  | -   | PTC0                           | ADC0_SE14/<br>TSI0_CH13 | ADC0_SE14/<br>TSI0_CH13 | PTC0                           |           | EXTRG_IN        |                | CMP0_OUT  |          |      |
| 56   | 44   | 34  | 22  | PTC1/<br>LLWU_P6/<br>RTC_CLKIN | ADC0_SE15/<br>TSI0_CH14 | ADC0_SE15/<br>TSI0_CH14 | PTC1/<br>LLWU_P6/<br>RTC_CLKIN | I2C1_SCL  |                 | TPM0_CH0       |           |          |      |
| 57   | 45   | 35  | 23  | PTC2                           | ADC0_SE11/<br>TSI0_CH15 | ADC0_SE11/<br>TSI0_CH15 | PTC2                           | I2C1_SDA  |                 | TPM0_CH1       |           |          |      |
| 58   | 46   | 36  | 24  | PTC3/<br>LLWU_P7               | DISABLED                |                         | PTC3/<br>LLWU_P7               |           | UART1_RX        | TPM0_CH2       | CLKOUT    |          |      |
| 59   | 47   | -   | _   | VSS                            | VSS                     | VSS                     |                                |           |                 |                |           |          |      |
| 60   | 48   | _   | _   | VDD                            | VDD                     | VDD                     |                                |           |                 |                |           |          |      |
| 61   | 49   | 37  | 25  | PTC4/<br>LLWU_P8               | DISABLED                |                         | PTC4/<br>LLWU_P8               | SPI0_PCS0 | UART1_TX        | TPM0_CH3       |           |          |      |
| 62   | 50   | 38  | 26  | PTC5/<br>LLWU_P9               | DISABLED                |                         | PTC5/<br>LLWU_P9               | SPI0_SCK  | LPTMR0_<br>ALT2 |                |           | CMP0_OUT |      |
| 63   | 51   | 39  | 27  | PTC6/<br>LLWU_P10              | CMP0_IN0                | CMP0_IN0                | PTC6/<br>LLWU_P10              | SPI0_MOSI | EXTRG_IN        |                | SPI0_MISO |          |      |
| 64   | 52   | 40  | 28  | PTC7                           | CMP0_IN1                | CMP0_IN1                | PTC7                           | SPI0_MISO |                 |                | SPI0_MOSI |          |      |
| 65   | 53   | -   | _   | PTC8                           | CMP0_IN2                | CMP0_IN2                | PTC8                           | I2C0_SCL  | TPM0_CH4        |                |           |          |      |
| 66   | 54   | -   | -   | PTC9                           | CMP0_IN3                | CMP0_IN3                | PTC9                           | I2C0_SDA  | TPM0_CH5        |                |           |          |      |
| 67   | 55   | -   | _   | PTC10                          | DISABLED                |                         | PTC10                          | I2C1_SCL  |                 |                |           |          |      |
| 68   | 56   | -   | _   | PTC11                          | DISABLED                |                         | PTC11                          | I2C1_SDA  |                 |                |           |          |      |
| 69   | -    | _   |     | PTC12                          | DISABLED                |                         | PTC12                          |           |                 | TPM_<br>CLKIN0 |           |          |      |
| 70   | -    | -   | _   | PTC13                          | DISABLED                |                         | PTC13                          |           |                 | TPM_<br>CLKIN1 |           |          |      |
| 71   | _    | -   | 1   | PTC16                          | DISABLED                |                         | PTC16                          |           |                 |                |           |          |      |
| 72   | _    | _   |     | PTC17                          | DISABLED                |                         | PTC17                          |           |                 |                |           |          |      |



| 80<br>LQFP | 64<br>LQFP | 48<br>QFN | 32<br>QFN | Pin Name          | Default   | ALT0      | ALT1              | ALT2      | ALT3     | ALT4     | ALT5      | ALT6 | ALT7 |
|------------|------------|-----------|-----------|-------------------|-----------|-----------|-------------------|-----------|----------|----------|-----------|------|------|
| 73         | 57         | 41        | _         | PTD0              | DISABLED  |           | PTD0              | SPI0_PCS0 |          | TPM0_CH0 |           |      |      |
| 74         | 58         | 42        | _         | PTD1              | ADC0_SE5b | ADC0_SE5b | PTD1              | SPI0_SCK  |          | TPM0_CH1 |           |      |      |
| 75         | 59         | 43        | -         | PTD2              | DISABLED  |           | PTD2              | SPI0_MOSI | UART2_RX | TPM0_CH2 | SPI0_MISO |      |      |
| 76         | 60         | 44        | _         | PTD3              | DISABLED  |           | PTD3              | SPI0_MISO | UART2_TX | TPM0_CH3 | SPI0_MOSI |      |      |
| 77         | 61         | 45        | 29        | PTD4/<br>LLWU_P14 | DISABLED  |           | PTD4/<br>LLWU_P14 | SPI1_PCS0 | UART2_RX | TPM0_CH4 |           |      |      |
| 78         | 62         | 46        | 30        | PTD5              | ADC0_SE6b | ADC0_SE6b | PTD5              | SPI1_SCK  | UART2_TX | TPM0_CH5 |           |      |      |
| 79         | 63         | 47        | 31        | PTD6/<br>LLWU_P15 | ADC0_SE7b | ADC0_SE7b | PTD6/<br>LLWU_P15 | SPI1_MOSI | UART0_RX |          | SPI1_MISO |      |      |
| 80         | 64         | 48        | 32        | PTD7              | DISABLED  |           | PTD7              | SPI1_MISO | UARTO_TX |          | SPI1_MOSI |      |      |

# 5.2 KL25 pinouts

The following figures show the pinout diagrams for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see KL25 Signal Multiplexing and Pin Assignments.



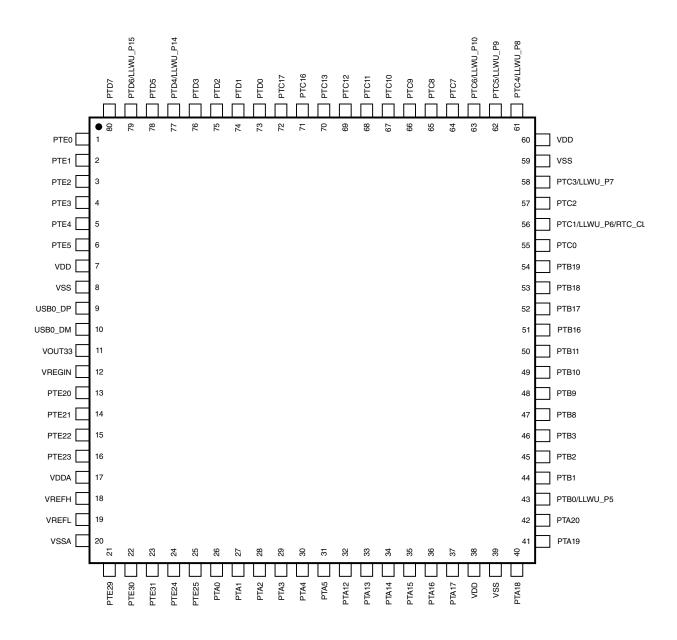


Figure 19. KL25 80-pin LQFP pinout diagram



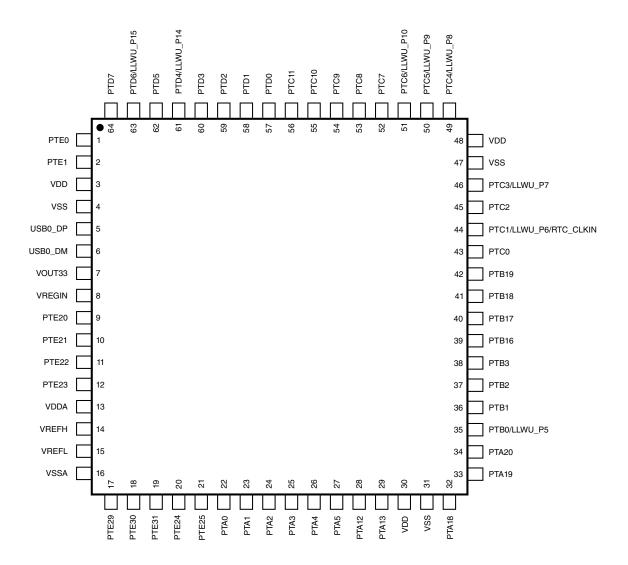


Figure 20. KL25 64-pin LQFP pinout diagram



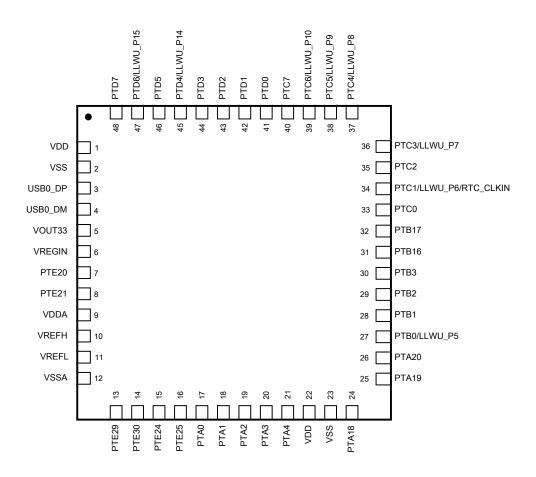


Figure 21. KL25 48-pin QFN pinout diagram

Freescale Semiconductor, Inc.



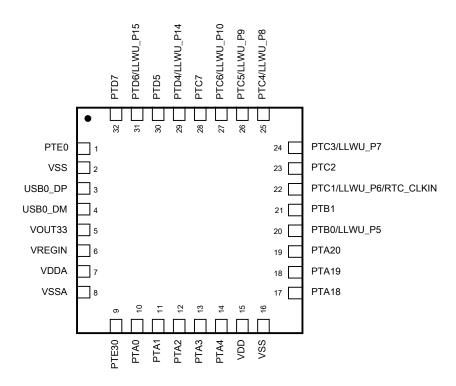


Figure 22. KL25 32-pin QFN pinout diagram

# 6 Ordering parts

#### 6.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to **freescale.com** and perform a part number search for the following device numbers: PKL25 and MKL25

#### 7 Part identification



## 7.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

## 7.2 Format

Part numbers for this device have the following format:

Q KL## A FFF R T PP CC N

#### 7.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Table 37. Part number fields descriptions

| Field | Description                 | Values   |
|-------|-----------------------------|--|
| Q     | Qualification status        | <ul> <li>M = Fully qualified, general market flow</li> <li>P = Prequalification</li> </ul>   |
| KL##  | Kinetis family              | • KL25   |
| A     | Key attribute               | • Z = Cortex-M0+   |
| FFF   | Program flash memory size   | <ul> <li>32 = 32 KB</li> <li>64 = 64 KB</li> <li>128 = 128 KB</li> </ul>   |
| R     | Silicon revision            | <ul><li>(Blank) = Main</li><li>A = Revision after main</li></ul>   |
| Т     | Temperature range (°C)      | • V = -40 to 105   |
| PP    | Package identifier          | <ul> <li>FM = 32 QFN (5 mm x 5 mm)</li> <li>FT = 48 QFN (7 mm x 7 mm)</li> <li>LH = 64 LQFP (10 mm x 10 mm)</li> <li>LK = 80 LQFP (12 mm x 12 mm)</li> </ul> |
| CC    | Maximum CPU frequency (MHz) | • 4 = 48 MHz   |
| N     | Packaging type              | <ul><li>R = Tape and reel</li><li>(Blank) = Trays</li></ul>  |



#### 7.4 Example

This is an example part number:

MKL25Z64VLK4

# 8 Terminology and guidelines

#### 8.1 Definition: Operating requirement

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

#### 8.1.1 Example

This is an example of an operating requirement:

| Symbol   | Description               | Min. | Max. | Unit |
|----------|---------------------------|------|------|------|
| $V_{DD}$ | 1.0 V core supply voltage | 0.9  | 1.1  | V    |

## 8.2 Definition: Operating behavior

Unless otherwise specified, an *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

#### 8.2.1 Example

This is an example of an operating behavior:

| Symbol   | Description                                  | Min. | Max. | Unit |
|----------|--|------|------|------|
| $I_{WP}$ | Digital I/O weak pullup/<br>pulldown current | 10   | 130  | μΑ   |

#### 8.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

#### 8.3.1 Example

This is an example of an attribute:

| Symbol | Description                     | Min. | Max. | Unit |
|--------|---------------------------------|------|------|------|
| CIN_D  | Input capacitance: digital pins | _    | 7    | pF   |

# 8.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

- Operating ratings apply during operation of the chip.
- Handling ratings apply when the chip is not powered.

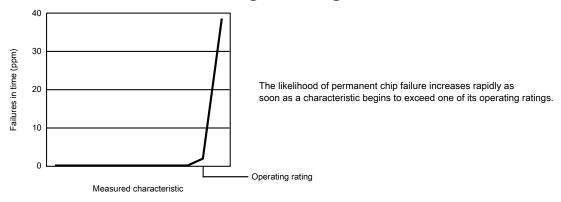
#### 8.4.1 Example

This is an example of an operating rating:

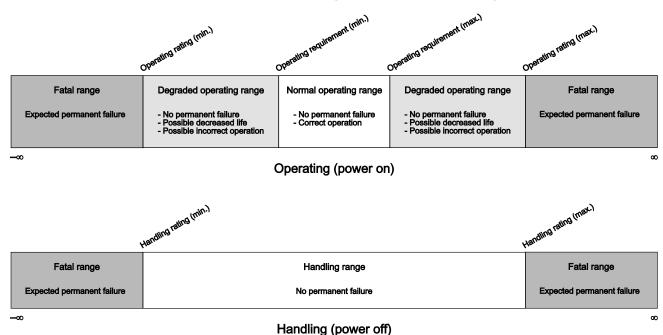
| Symbol   | Description               | Min. | Max. | Unit |
|----------|---------------------------|------|------|------|
| $V_{DD}$ | 1.0 V core supply voltage | -0.3 | 1.2  | V    |



## 8.5 Result of exceeding a rating



## 8.6 Relationship between ratings and operating requirements



# 8.7 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip's ratings.
- During normal operation, don't exceed any of the chip's operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.

#### 8.8 Definition: Typical value

A typical value is a specified value for a technical characteristic that:

- Lies within the range of values specified by the operating behavior
- Given the typical manufacturing process, is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions

Typical values are provided as design guidelines and are neither tested nor guaranteed.

#### 8.8.1 **Example 1**

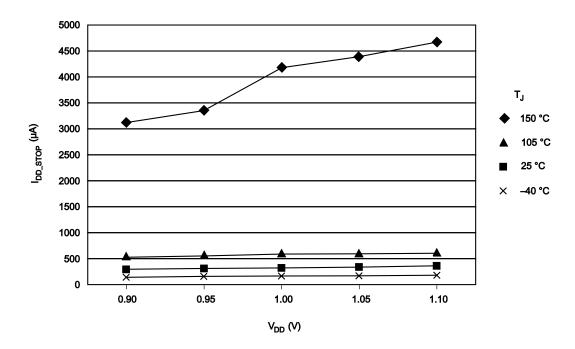
This is an example of an operating behavior that includes a typical value:

| Symbol          | Description                              | Min. | Тур. | Max. | Unit |
|-----------------|--|------|------|------|------|
| I <sub>WP</sub> | Digital I/O weak pullup/pulldown current | 10   | 70   | 130  | μΑ   |

#### 8.8.2 Example 2

This is an example of a chart that shows typical values for various voltage and temperature conditions:





# 8.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Table 38. Typical value conditions

| Symbol          | Description          | Value | Unit |
|-----------------|----------------------|-------|------|
| T <sub>A</sub>  | Ambient temperature  | 25    | °C   |
| V <sub>DD</sub> | 3.3 V supply voltage | 3.3   | V    |

# 9 Revision history

The following table provides a revision history for this document.

Table 39. Revision history

| Rev. No. | Date   | Substantial Changes   |
|----------|--------|---|
| 2        | 9/2012 | Completed all the TBDs, initial public release.                             |
| 3        | 9/2012 | Updated Signal Multiplexing and Pin Assignments table to add UART2 signals. |
| 4        | 3/2014 | Updated the front page and restructured the chapters                        |

Table continues on the next page...



# Table 39. Revision history (continued)

| Rev. No. | Date    | Substantial Changes  |
|----------|---------|--|
|          |         | <ul> <li>Added a note to the I<sub>LAT</sub> in the ESD handling ratings</li> <li>Updated Voltage and current operating requirements</li> <li>Updated the Voltage and current operating behaviors</li> <li>Updated Power mode transition operating behaviors</li> <li>Updated Capacitance attributes</li> <li>Updated footnote in the Device clock specifications</li> <li>Updated t<sub>ersall</sub> in the Flash timing specifications — commands</li> <li>Updated VADIN in the 16-bit ADC operating conditions</li> <li>Updated Temp sensor slope and voltage and added a note to them in the 16-bit ADC electrical characteristics</li> <li>Removed T<sub>A</sub> in the 12-bit DAC operating requirements</li> <li>Added Inter-Integrated Circuit Interface (I2C) timing</li> </ul> |
| 5        | 08/2014 | <ul> <li>Updated related source and added block diagram in the front page</li> <li>Updated Power consumption operating behaviors</li> <li>Updated the note in USB electrical specifications</li> </ul>   |





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